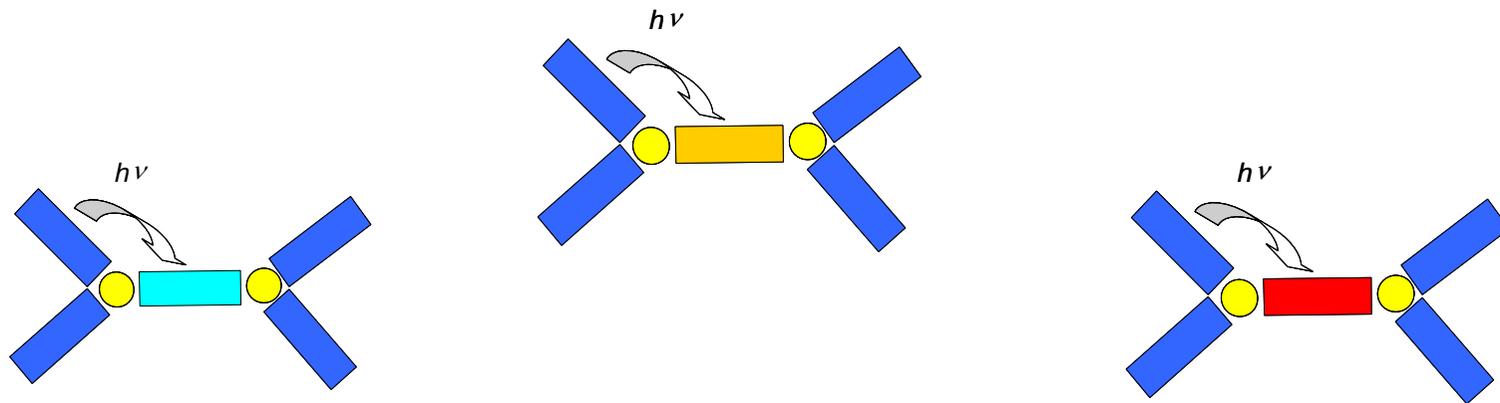


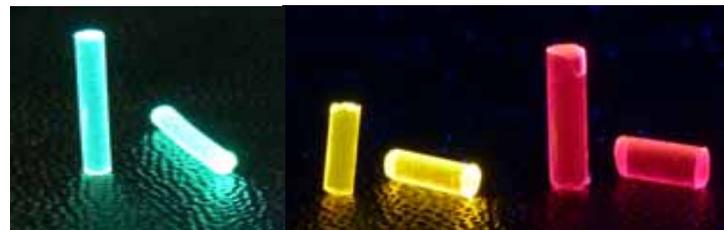
# New materials for organic photodetectors, wavelength sifters and plastic scintillators



**Sergey Ponomarenko, Oleg Borschev, Nikolay Surin**

Institute of Synthetic Polymeric Materials of Russian Academy of Sciences  
(ISPM RAS), Moscow, Russia

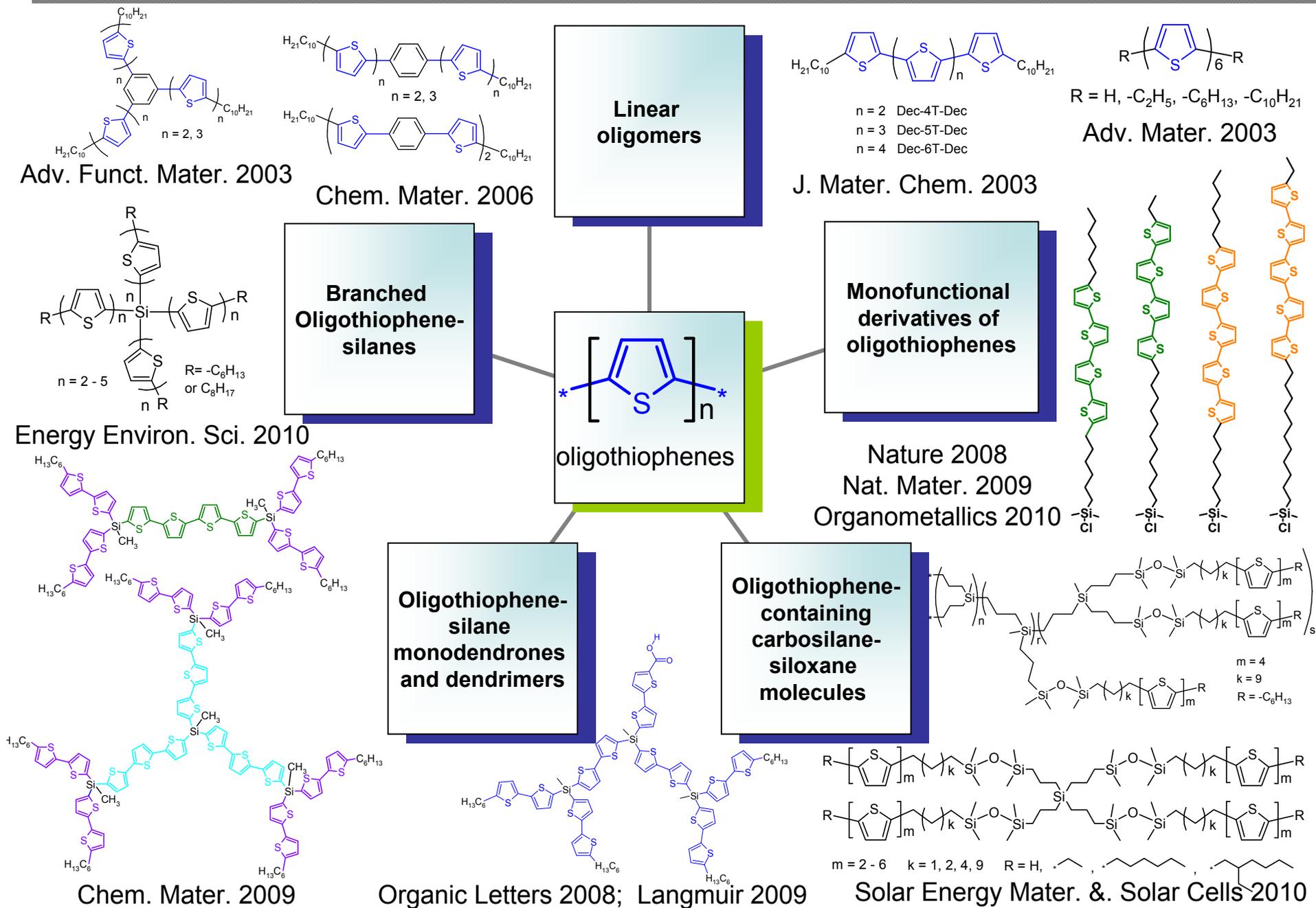
Luminescent Innovation Technologies LLC, Skolkovo (Moscow region), Russia



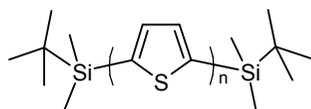
## OUTLINE

- Introduction
- Materials for organic solar cells and photodetectors
- Organosilicon nanostructured luminophores (ONL)
- Plastic scintillators with ONL
- Organosilicon wavelength shifters (Si-WLS)

# Functional materials for Organic Electronics and Photonics @ ISPM RAS



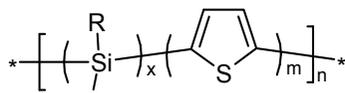
# Oligo- and polyarylsilanes of different molecular structure



$n = 3 - 6$

**tBuMe<sub>2</sub>Si-Tn-Si-Me<sub>2</sub>tBu**

Barbarella G, et. al., *Chem. Mater.* **1998**, 10, 3683

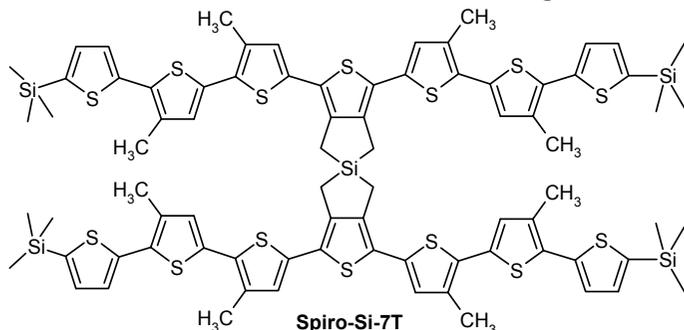


**MSmT**,  $x=1$ ,  $m = 3-5$ ,  $R=Et$

**DSmT**,  $x=2$ ,  $m = 3-5$ ,  $R=Et$

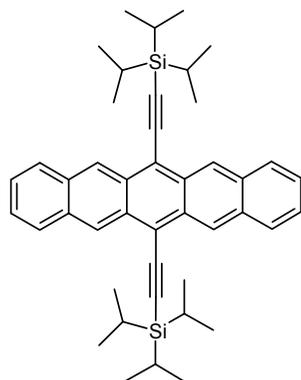
**TSmT**,  $x=3$ ,  $m = 3-5$ ,  $R=Me$

Kunai A. et.al., *Organometallics* **1996**, 15, 2000



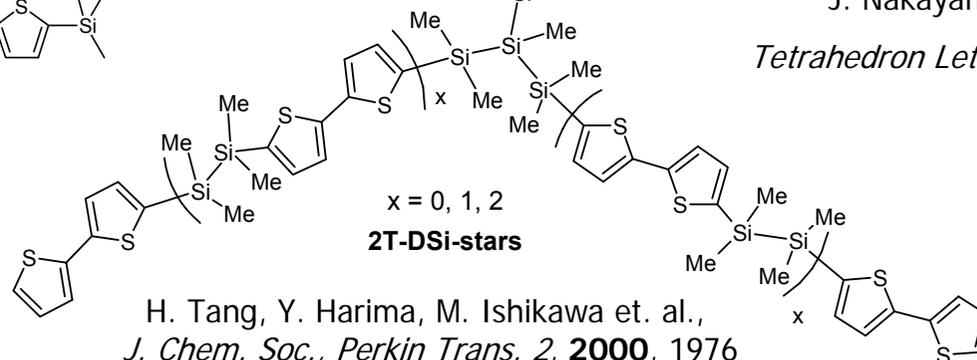
**Spiro-Si-7T**

Guay J, Diaz A, Wu R, Tour JM, *J Am Chem Soc* **1993**, 115, 1869



**TIPS-5AC**

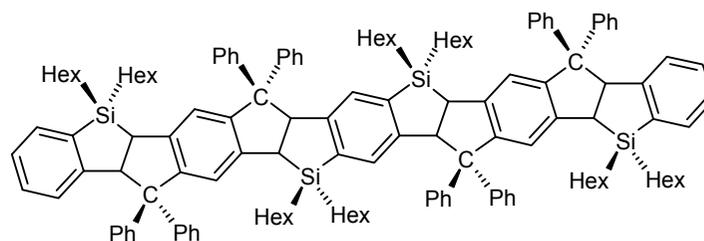
Anthony JE et. al. *J Am Chem Soc* **2001**, 123, 9482



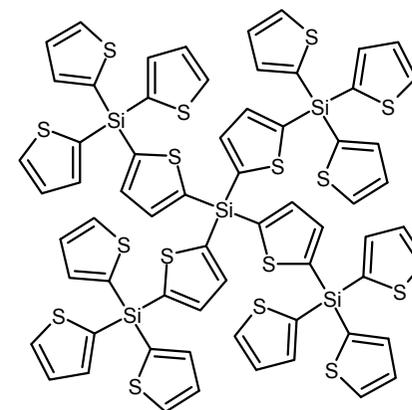
$x = 0, 1, 2$

**2T-DSi-stars**

H. Tang, Y. Harima, M. Ishikawa et. al., *J. Chem. Soc., Perkin Trans. 2*, **2000**, 1976

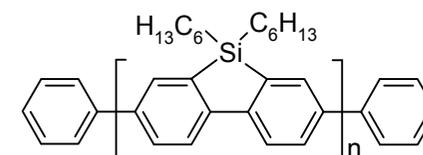


Xu C, Wakamiya A, Yamaguchi S *J Am Chem Soc* **2005**, 127, 1638



J. Nakayama, J.-S. Lin,

*Tetrahedron Lett.* **1997**, 38, 6043

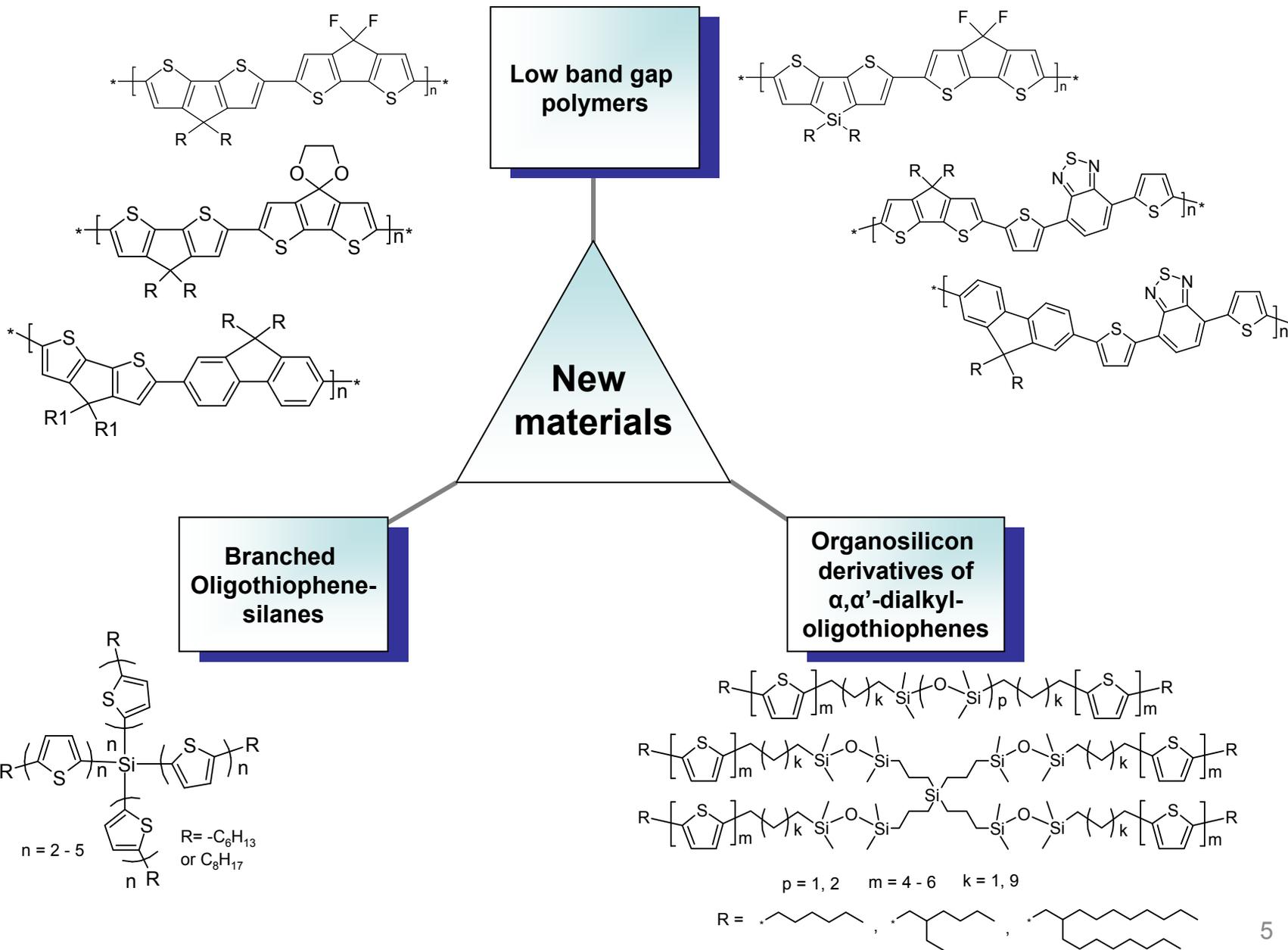


Holmes AB, et. al.,

*J Am Chem Soc* **2005**, 127, 7662

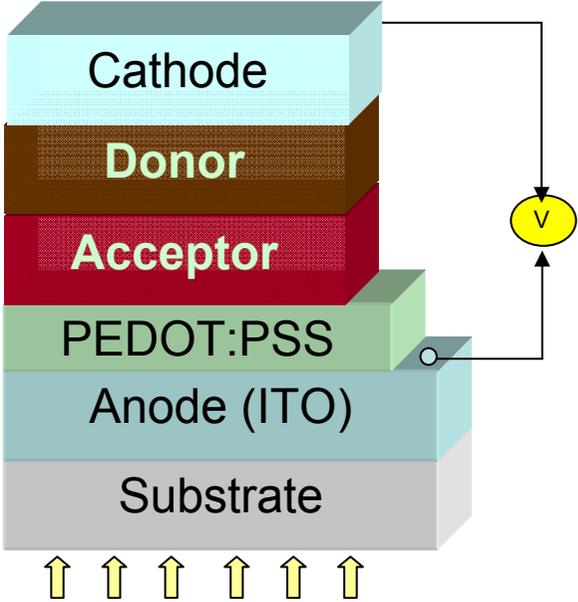
See review: S.A. Ponomarenko, S. Kirchmeyer, *Adv. Polym. Sci.*, **2011**, 235, 33 - 110.

# New materials for polymer BHJ solar cells and photodetectors

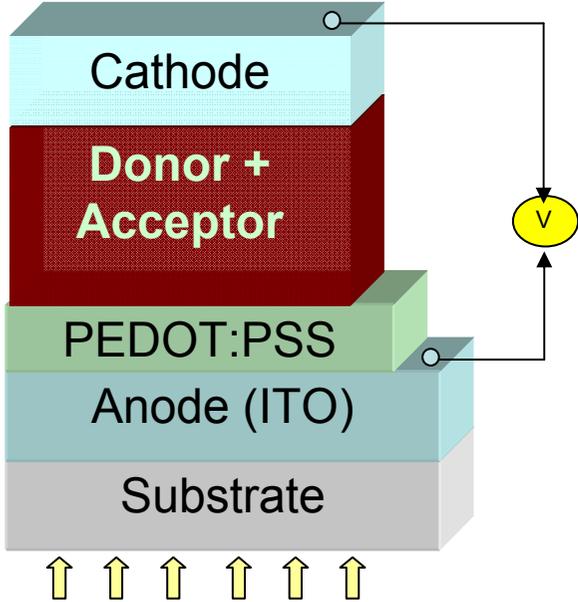


# Organic Photovoltaic Cells

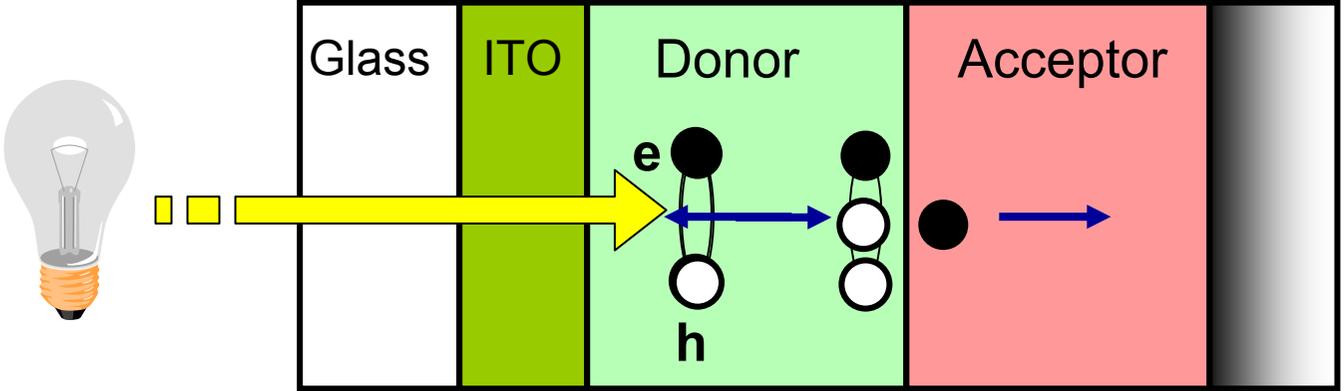
**Bilayer device**



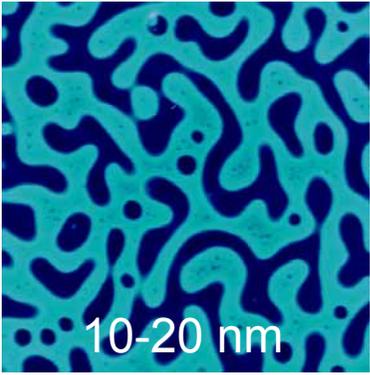
**Bulk-heterojunction device**



## Photoinduced Charge Generation



Donor-acceptor nanocomposite

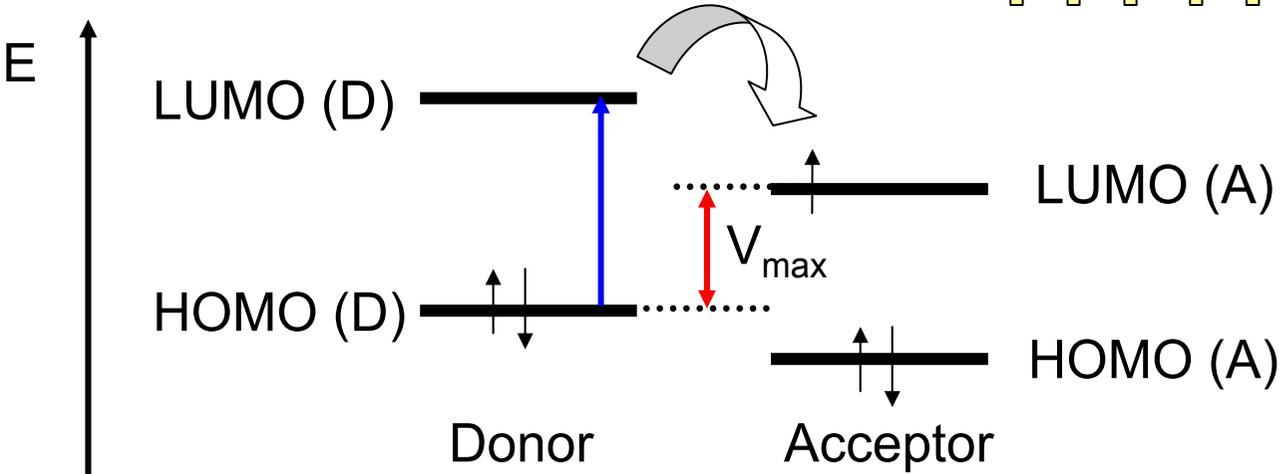
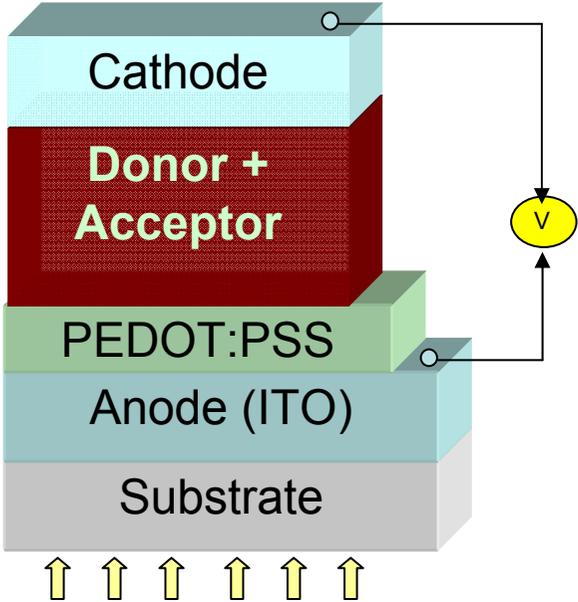


# Organic Photovoltaic Cells

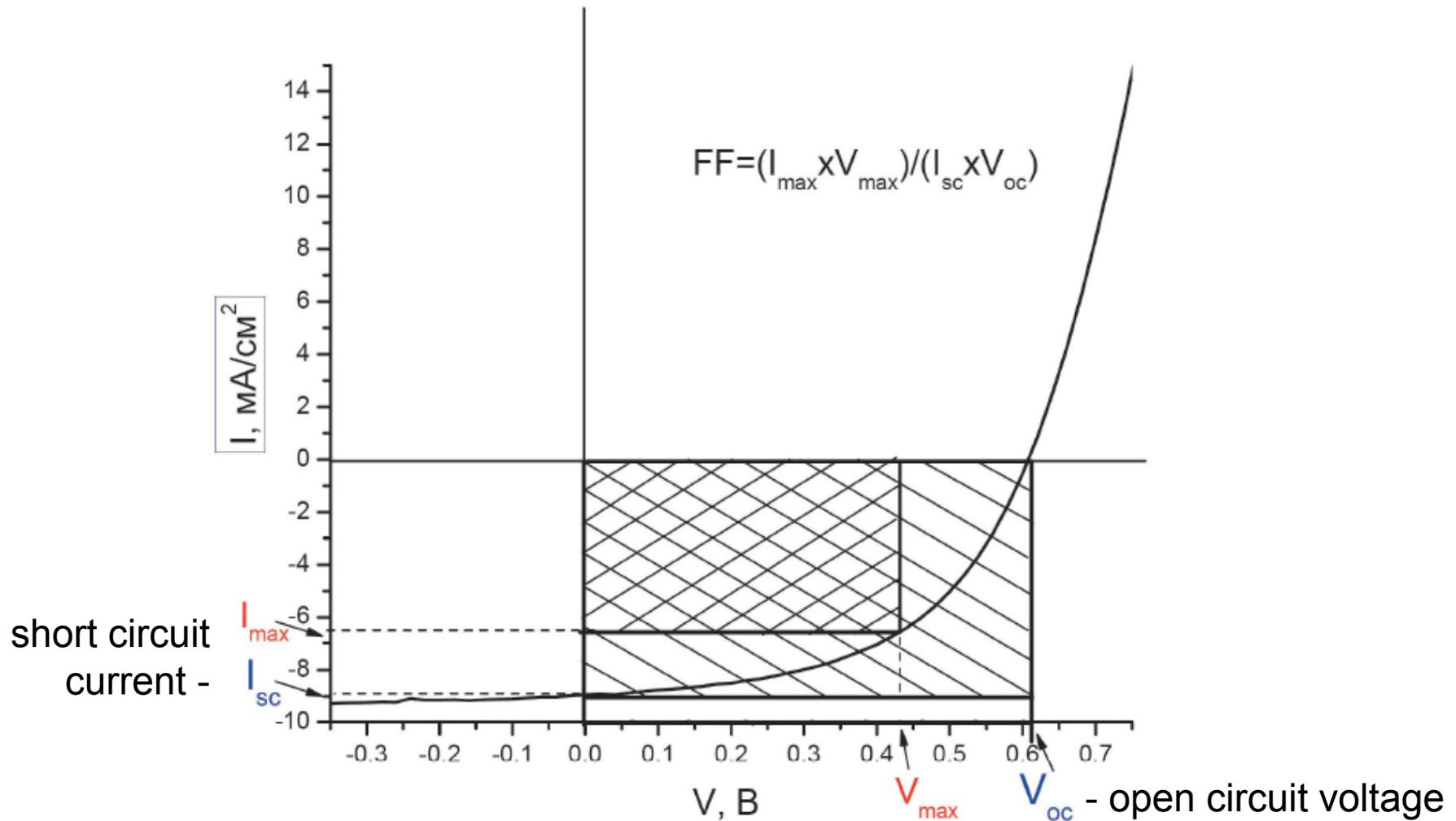
## Control:

- Absorption of the solar light
- Charge transport
- Solubility
- Morphology
- HOMO and LUMO energy levels of donor and acceptor

## Bulk-heterojunction device



# Typical electrical characteristics of photovoltaic cells



Power conversion efficiency  $\eta = \frac{I_{max} V_{max}}{P_{light}} \times 100\% = \frac{I_{sc} V_{oc} FF}{P_{light}} \times 100\%$

# Advantages of organic electronics

- Light weight
- Flexibility
- Large area
- Transparent
- Low-Cost
  - No vacuum processing
  - No lithography (printing)
  - Low-cost substrates (plastic, paper, even cloth...)
  - Direct integration on package (lower insertion costs)

## The production of plastic chips tomorrow

Continuous printing methods for low cost polymelectronics  
• by roll to roll printing

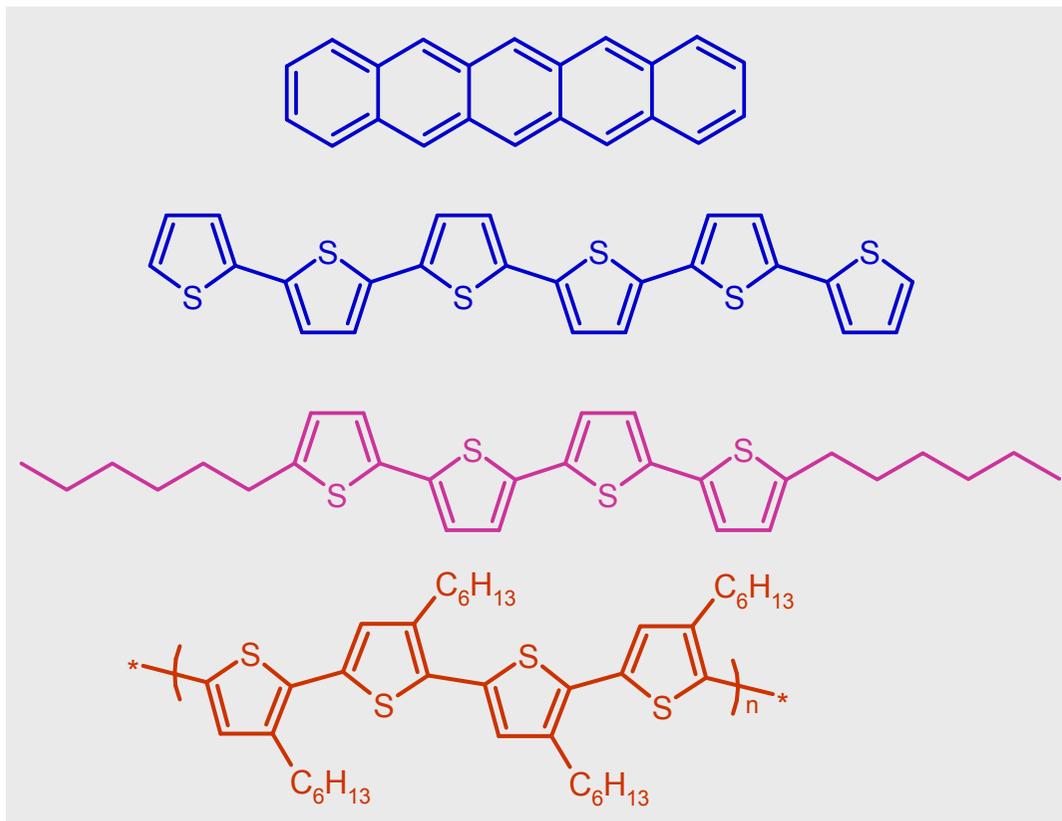


*"let's print electronics like a newspaper"*

# Organic Semiconducting materials

Evaporation

p-type (donors)



Pentacene

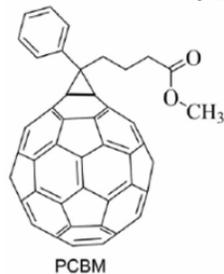
Sexithiophene

$\alpha, \alpha'$ -dihexyl-  
quaterthiophene

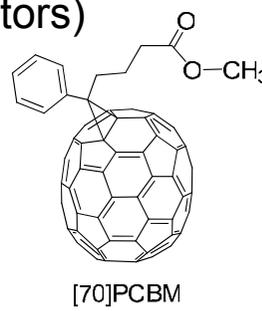
Poly(hexylthiophene)  
P3HT

Spincoating

n-type (acceptors)



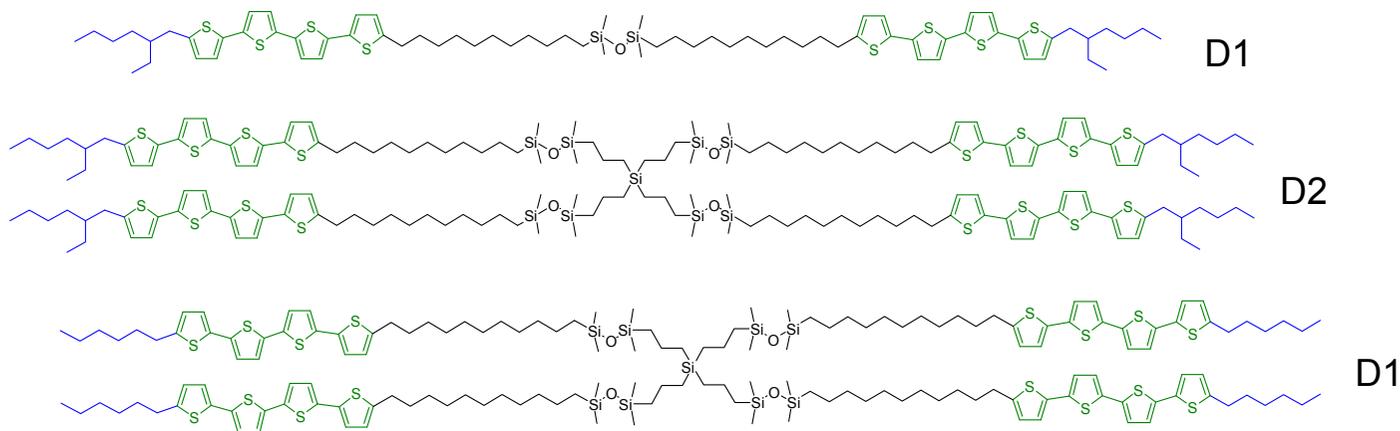
PCBM



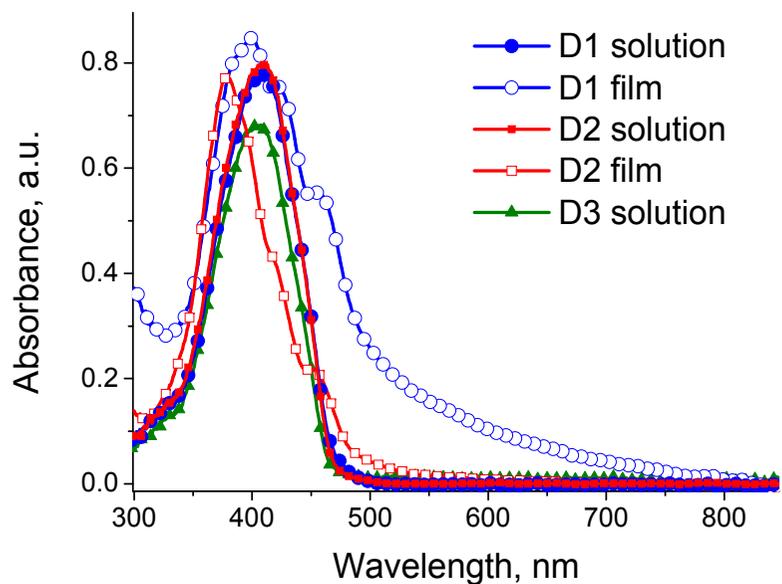
[70]PCBM

Soluble Fullerene  
derivatives

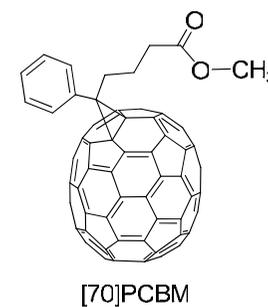
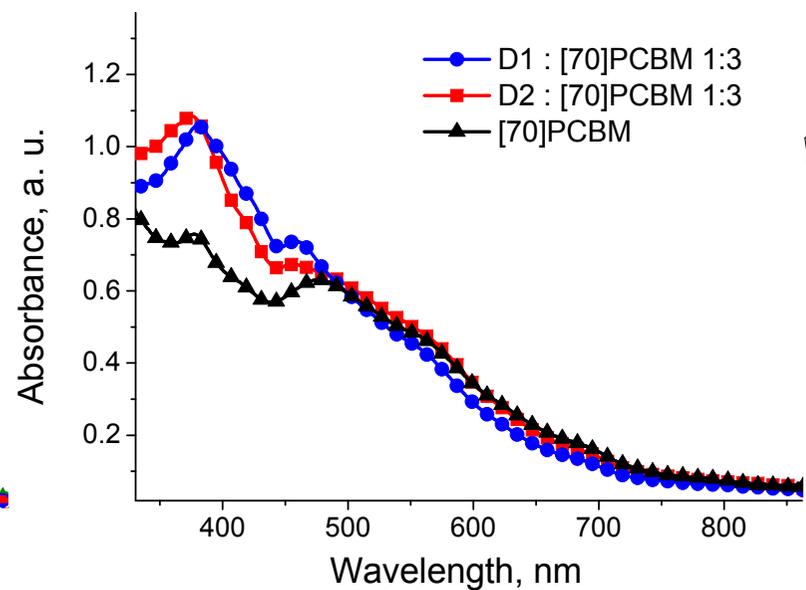
# Organosilicon derivatives of $\alpha,\alpha'$ -dialkyloligothiophenes



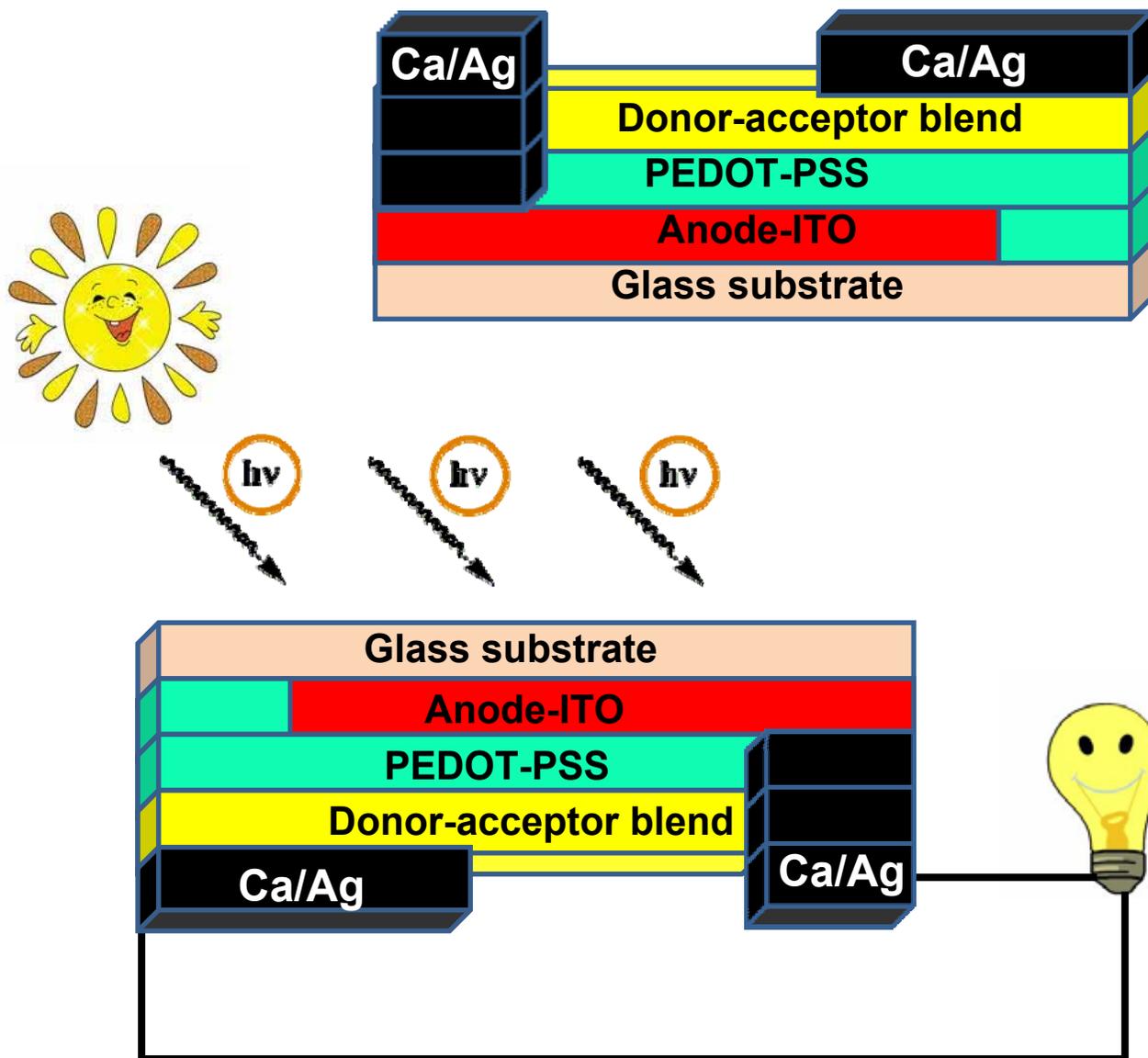
**UV- Vis absorption spectra**



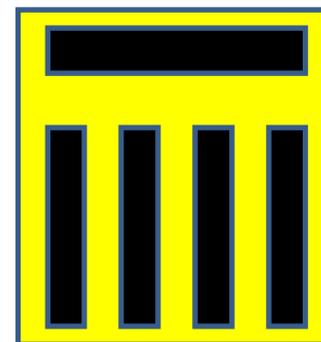
**Thin films absorption spectra**



# Preparation of test devices for organic photovoltaic cells



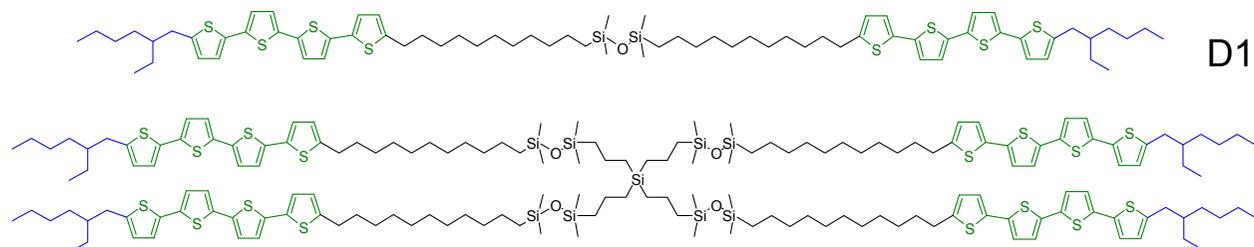
Schematic



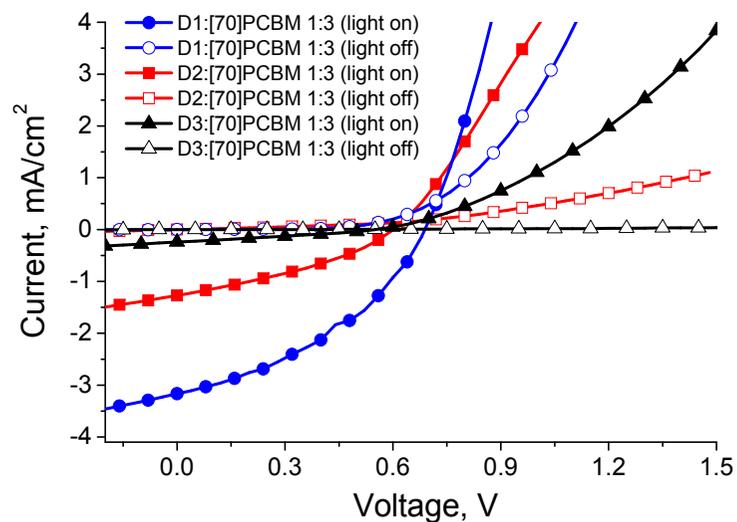
Photograph



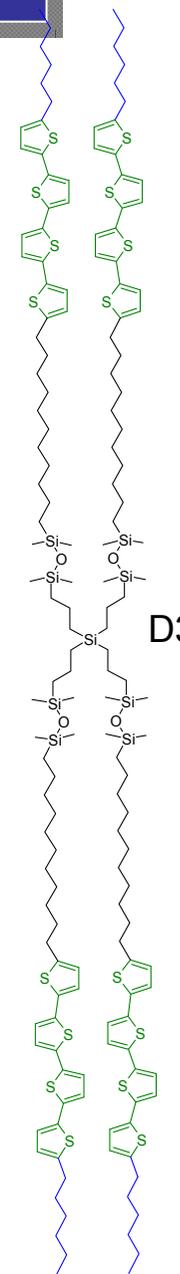
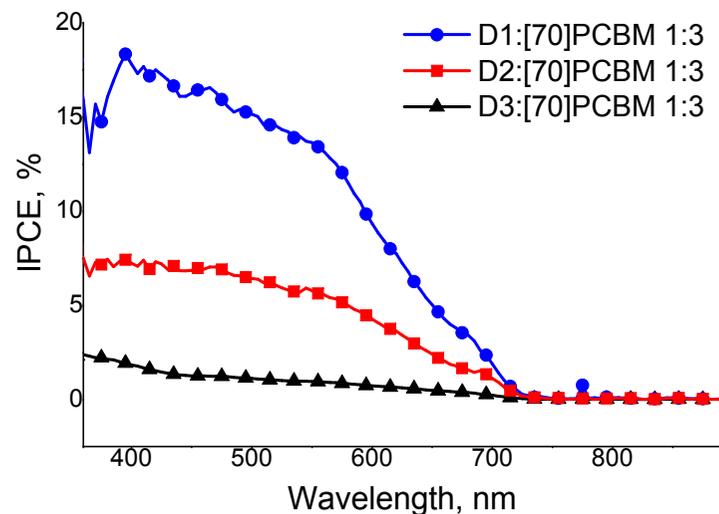
# Organosilicon derivatives of $\alpha,\alpha'$ -dialkyloligothiophenes



Light-on and light-off I-V curves



IPCE spectra



Compound	OFETs		Photovoltaic cells			
	$\mu$ , cm <sup>2</sup> /Vs	On/Off Ratio	$V_{oc}$ , mV	FF, %	$I_{sc}$ , mA/cm <sup>2</sup>	PCE, %
D1	-	-	680	40	3.2	0.9
D2	0,0002	260	600	35	1.3	0.27
D2	0,02	10 <sup>6</sup>	360	29	0.45	0.05

# Tetrakis(ter-, quater- and quinquethiophene)silanes

**PCE = 0.3 %**

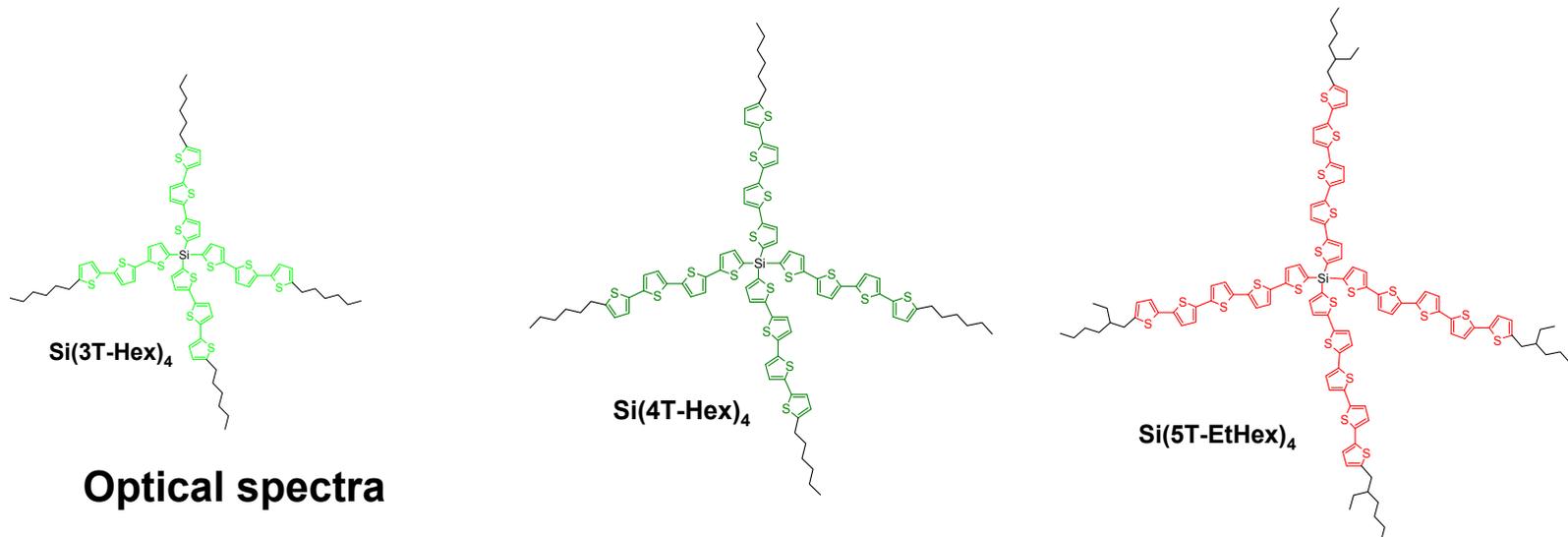
J. Roncali, et. al.,  
*J. Mater. Chem.*, **2006**,  
16, 3040

**Si(3T-Hex)<sub>4</sub>**

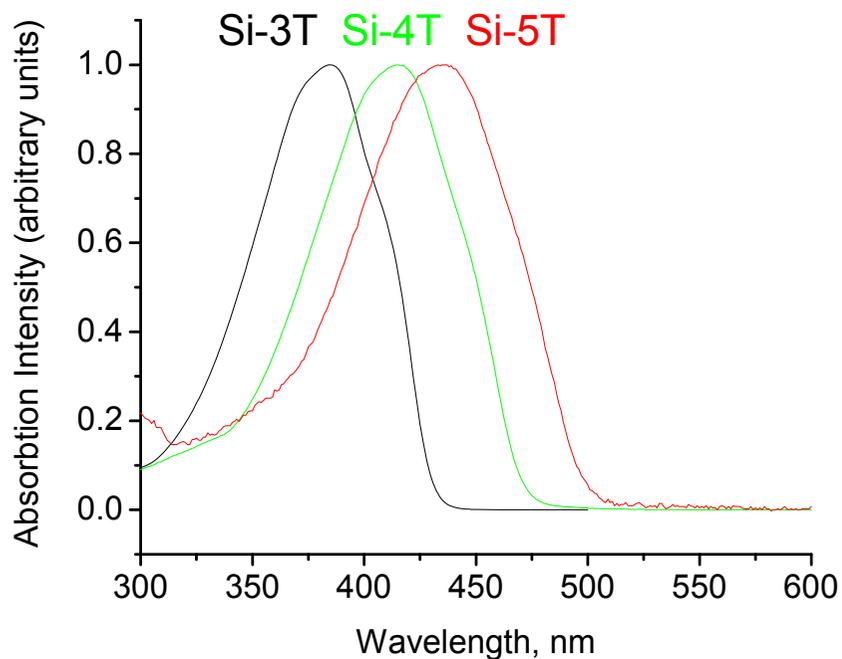
**Si(4T-Hex)<sub>4</sub>**

**Si(5T-EtHex)<sub>4</sub>**

# Tetrakis(ter-, quater- and quinquethiophene)silanes



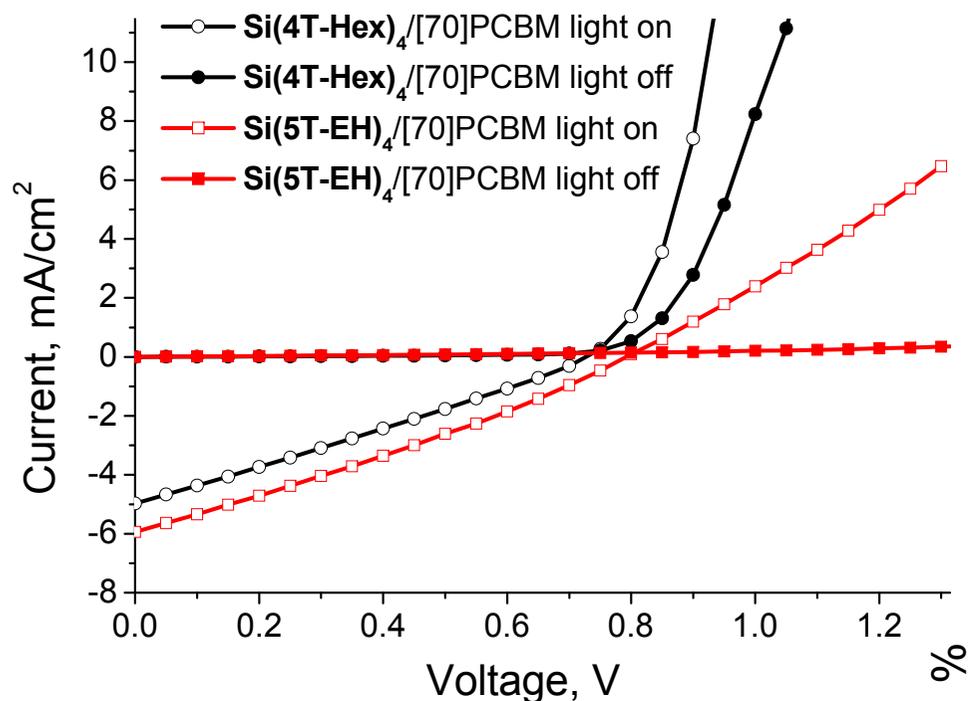
## Optical spectra



## Photovoltaic Efficiency

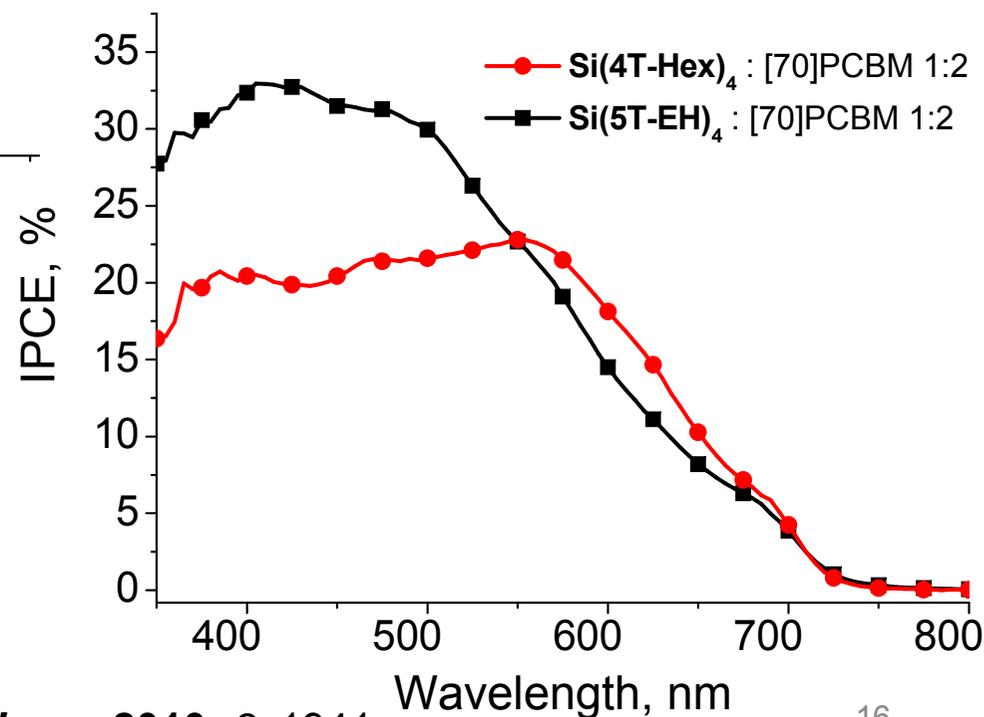
Compound	Photovoltaic cells			
	$V_{oc}$ , mV	FF, %	$I_{sc}$ , mA/cm <sup>2</sup>	PCE, %
Si-3T	830	25	2.9	0.6
Si-4T	750	26	5.0	1.0
Si-5T	<b>800</b>	<b>28</b>	<b>6.0</b>	<b>1.4</b>

## I-V characteristics and IPCE spectra of photovoltaic cells based on oligothiophenesilanes

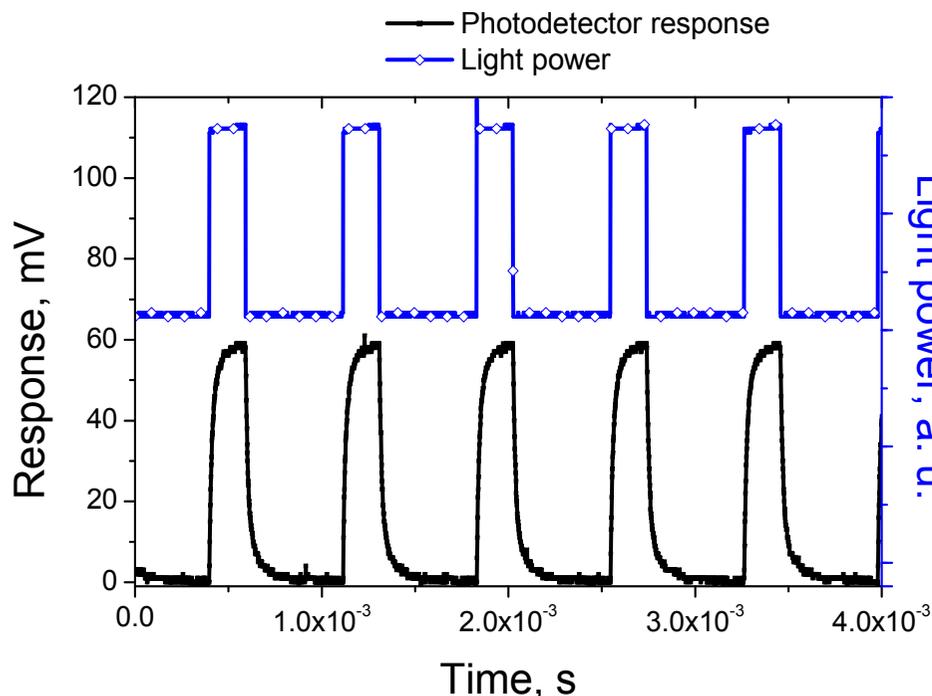


Light-on and light-off I-V curves for photovoltaic cells comprising blends **Si(4T-Hex)<sub>4</sub>/[70]PCBM** and **Si(5T-EH)<sub>4</sub>/[70]PCBM** in the photoactive layers

IPCE spectra for devices comprising **Si(4T-Hex)<sub>4</sub>/[70]PCBM** and **Si(5T-EH)<sub>4</sub>/[70]PCBM** blends in the active layers



# Photodetectors based on Si(4T-Hex)<sub>4</sub> / [70]PCBM BHJ

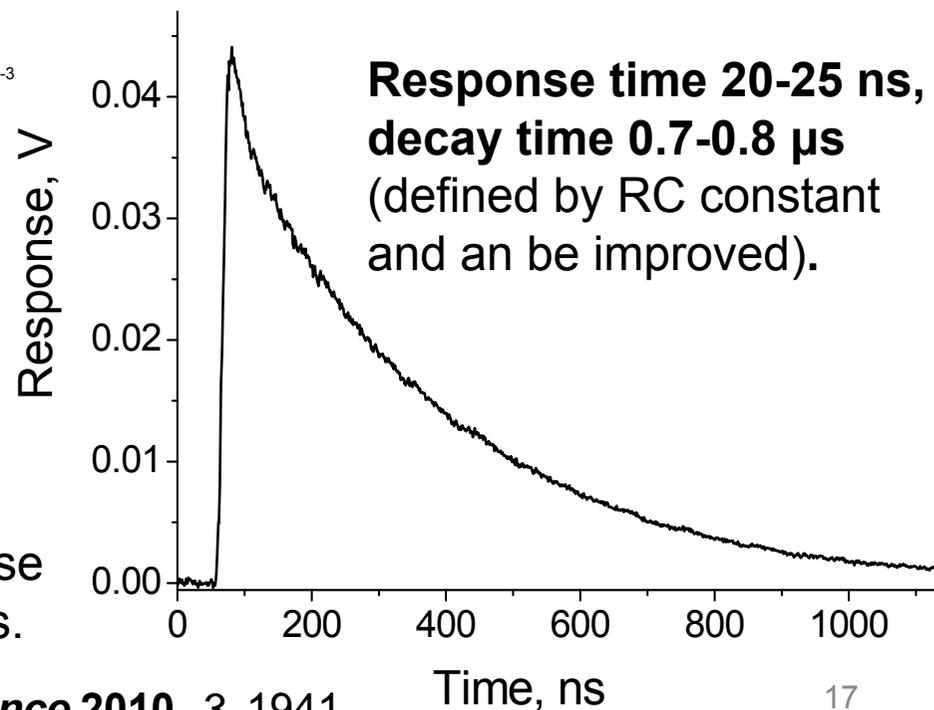


Detection of light pulses modulated at 5kHz with organic photodetector.

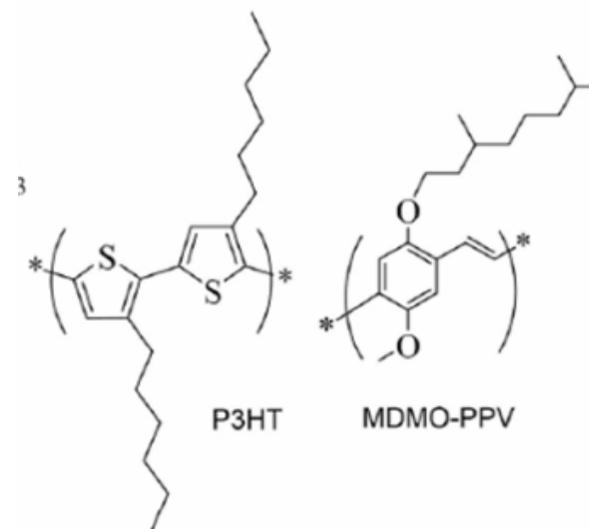
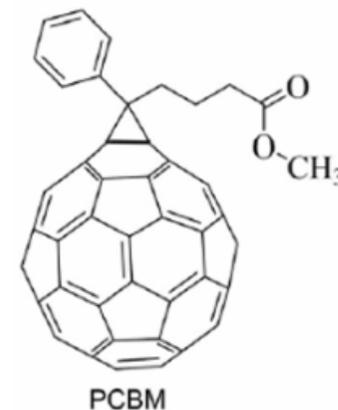
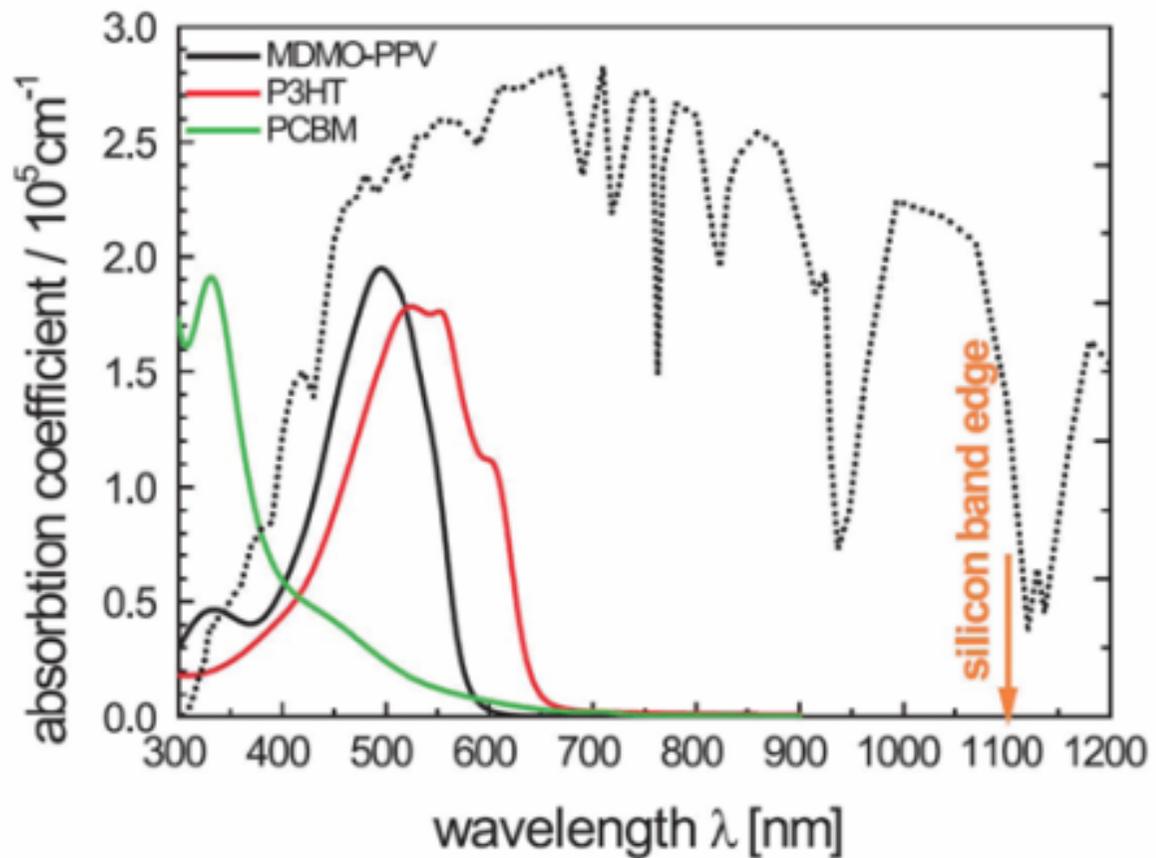
The reference devices based on P3HT/[70]PCBM blends yielded response time of 1–2  $\mu$ s and decay time of 3–4  $\mu$ s.

RC constant: 0.3  $\mu$ s  
Load resistance: 60  $\Omega$   
Device area: 0.12 cm<sup>2</sup>

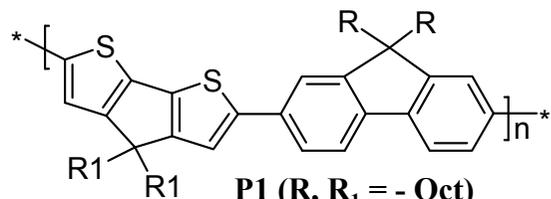
Transient response of organic photodetector to 10 ns light pulse from nitrogen laser (337 nm).



# Solar light spectra and absorption spectra of the mostly used materials

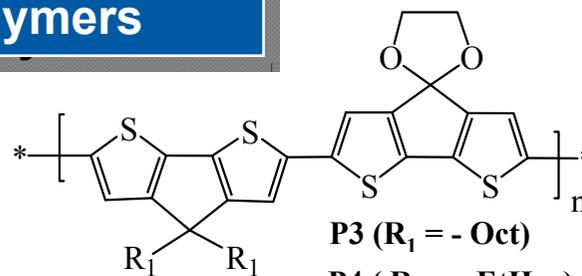


## Low band gap copolymers



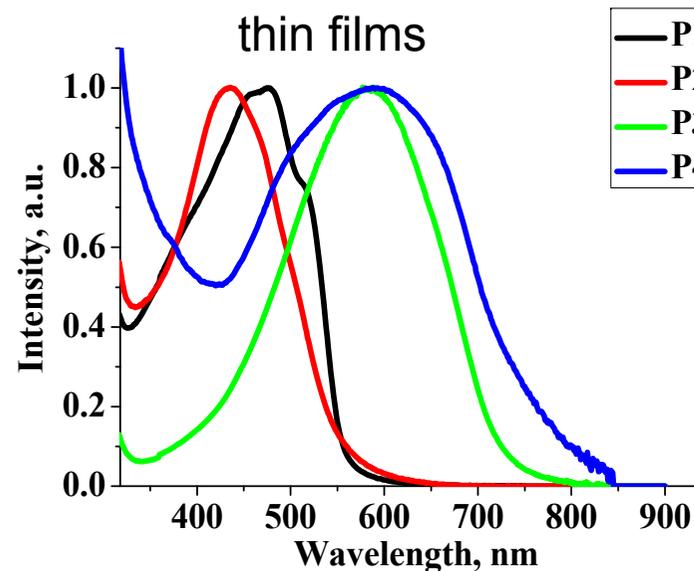
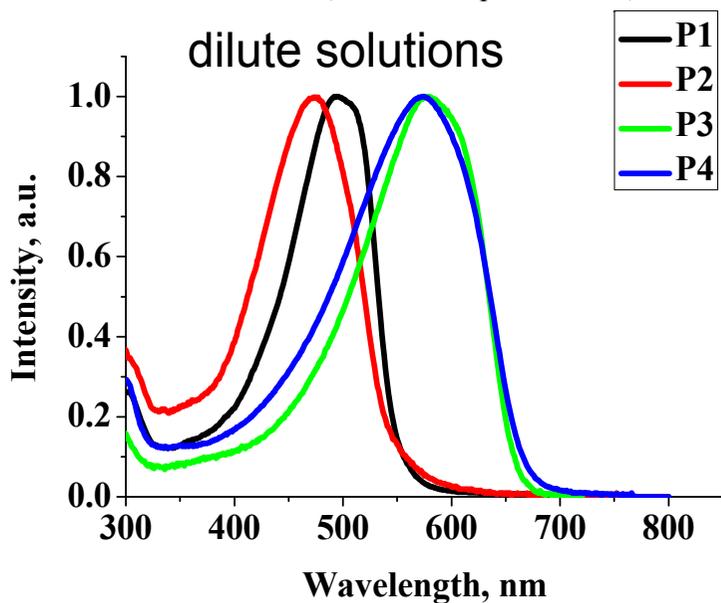
P1 (R, R<sub>1</sub> = - Oct)

P2 (R = Oct, R<sub>1</sub> = - EtHex)



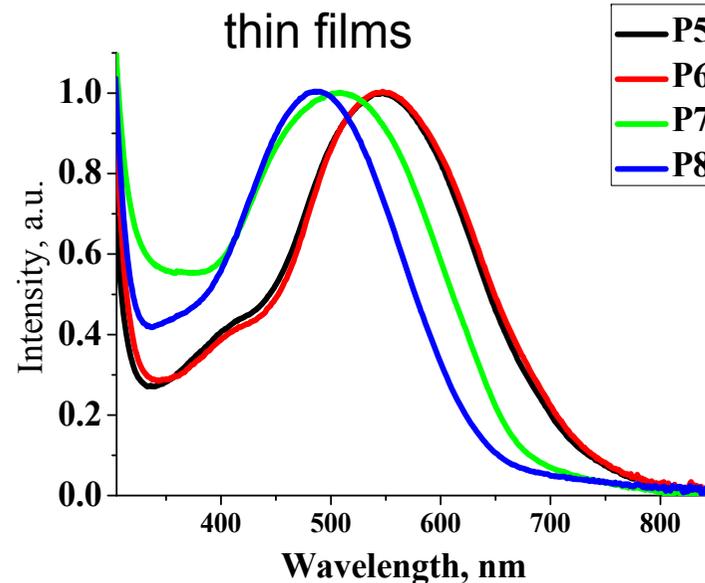
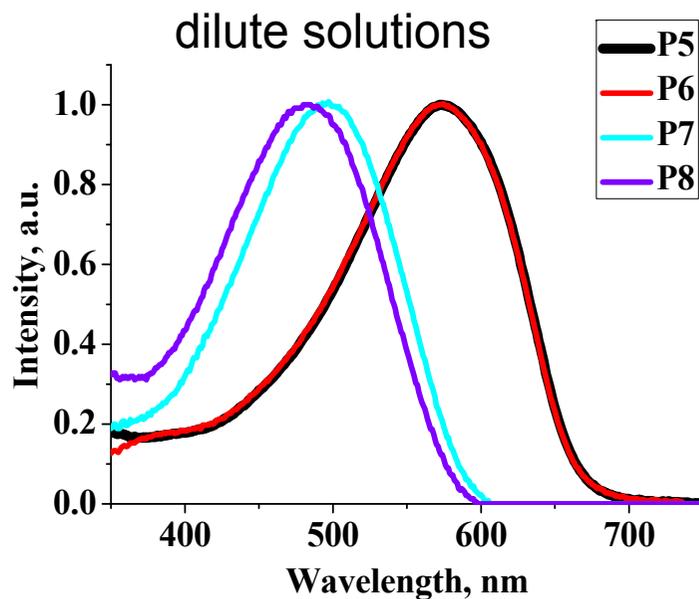
P3 (R<sub>1</sub> = - Oct)

P4 (R<sub>1</sub> = - EtHex)



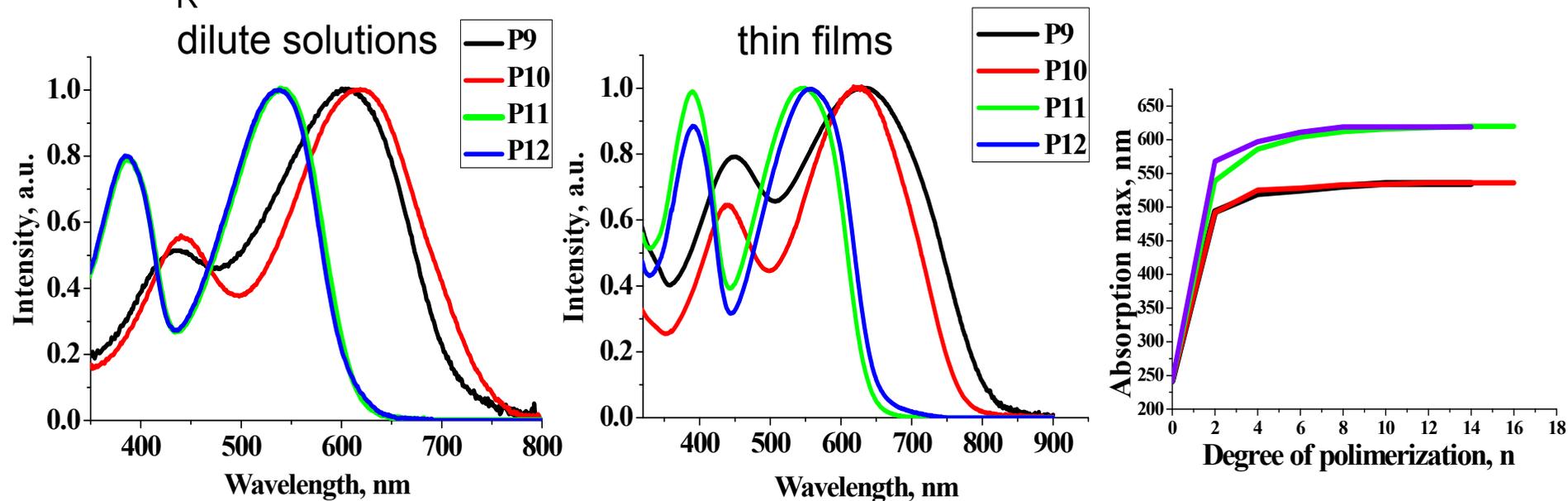
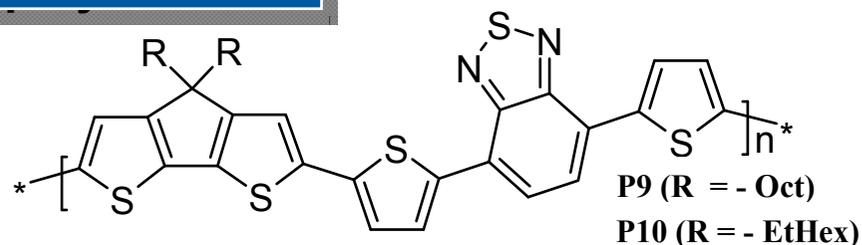
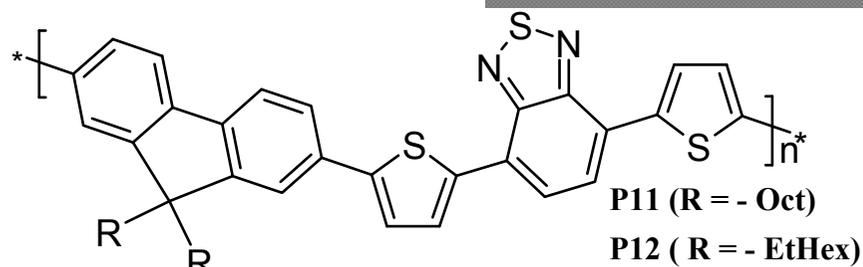
	Mn	Mw	DPI	$\lambda_{\max}$ , nm (solution)	$\lambda_{\max}$ , nm (film)	$\Delta E_{\text{opt}}$ eV, (solution)	$\Delta E_{\text{opt}}$ eV (film)
P1	8400	11900	1.42	495	478	2.24	2.21
P2	2700	4500	1.67	474	434	2.25	2.19
P3	7500	12500	1.67	574	585	1.89	1.69
P4	6700	10000	1.49	577	594	1.88	1.59

## Low band gap copolymers



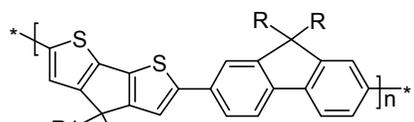
	<b>Mn</b>	<b>Mw</b>	<b>DPI</b>	$\lambda_{\max}$ , nm (solution)	$\lambda_{\max}$ , nm (film)	$\Delta E_{\text{opt}}$ , eV, (solution)	$\Delta E_{\text{opt}}$ , eV (film)
<b>P5</b>	11000	13900	1.26	573	547	1.85	1.60
<b>P6</b>	7900	10500	1.33	572	554	1.85	1.62
<b>P7</b>	4000	5000	1.20	495	510	2.11	1.79
<b>P8</b>	4600	6000	1.30	481	494	2.16	1.88

## Low band gap copolymers

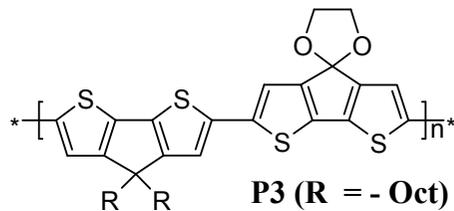


	Mn	Mw	DPI	$\lambda_{\max}$ , nm (solution)	$\lambda_{\max}$ , nm (film)	$\Delta E_{\text{opt}}$ , eV, (solution)	$\Delta E_{\text{opt}}$ , eV (film)
<b>P9</b>	18200	25500	1.40	609	637	1.73	1.55
<b>P10</b>	10600	15000	1.42	617	624	1.65	1.60
<b>P11</b>	9300	15700	1.63	538	545	2.03	1.92
<b>P12</b>	8300	12300	1.47	539	560	2.02	1.90

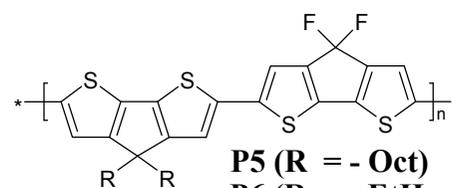
## Low band gap copolymers



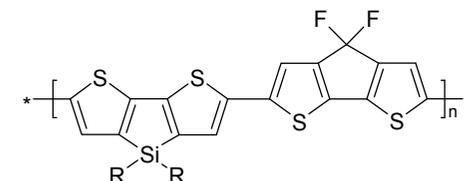
**P1** (R, R<sub>1</sub> = - Oct)  
**P2** (R = Oct, R<sub>1</sub> = - EtHex)



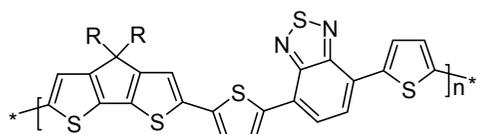
**P3** (R = - Oct)  
**P4** (R = - EtHex)



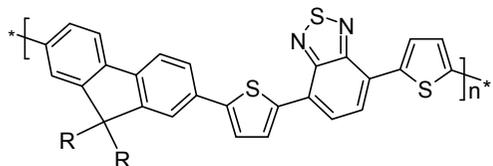
**P5** (R = - Oct)  
**P6** (R = - EtHex)



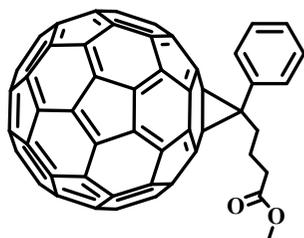
**P7** (R = - Oct)  
**P8** (R = - EtHex)



**P9** (R = - Oct)  
**P10** (R = - EtHex)



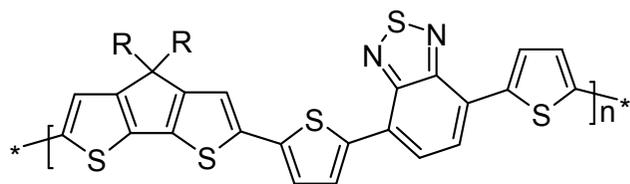
**P11** (R = - Oct)  
**P12** (R = - EtHex)



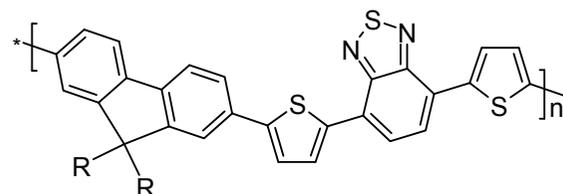
**F1** - [60]PCBM

No.	$\Delta E_{opt}$ eV, in film	P <sub>x</sub> / F1	I <sub>sc</sub> , mA/cm <sup>2</sup>	V <sub>oc</sub> , mV	FF, %	$\eta$ , %
<b>P1</b>	2.21	1 : 1	1.43	522	53	0.80
<b>P2</b>	2.19	1 : 2	2.94	561	32	0.20
<b>P3</b>	1.69	1 : 2	1.45	365	27	0.14
<b>P4</b>	1.59	1 : 2	3.10	565	41	0.70
<b>P5</b>	1.60	1 : 3	2.50	525	37	0.50
<b>P6</b>	1.62	1 : 3	2.10	516	37	0.41
<b>P7</b>	1.79	1 : 3	2.57	720	39	0.73
<b>P8</b>	1.88	1 : 4	1.57	631	33	0.33
<b>P9</b>	1.55	1 : 2	10.23	500	41	2.09
<b>P10</b>	1.60	1 : 2	3.70	500	35	0.65
<b>P11</b>	1.92	1 : 4	10.50	900	42	3.97
<b>P12</b>	1.90	1 : 4	8.1	900	35	2.55

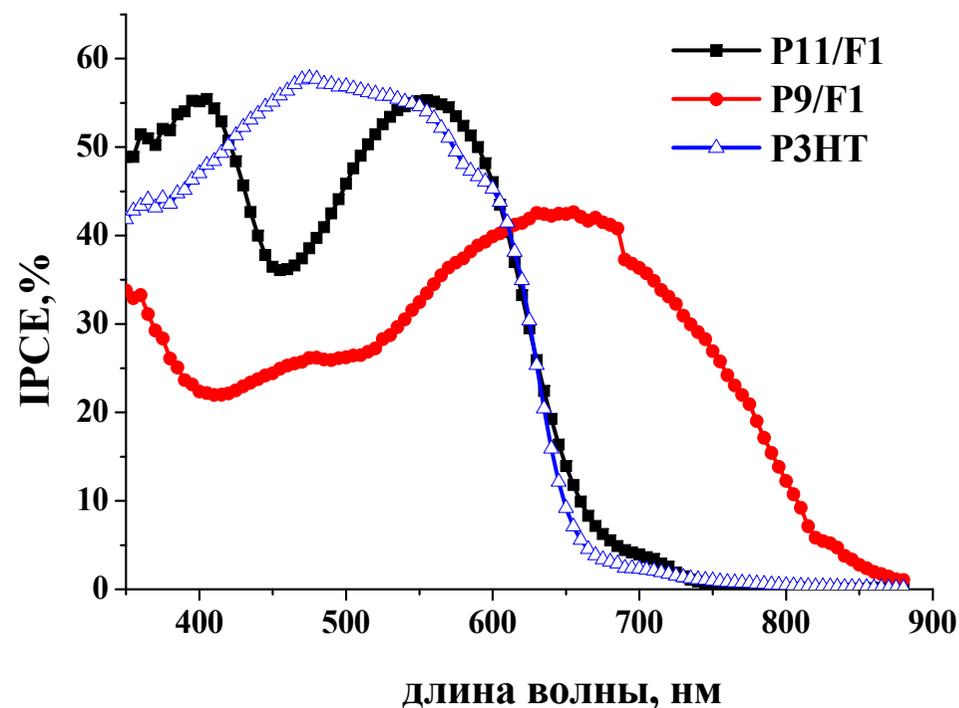
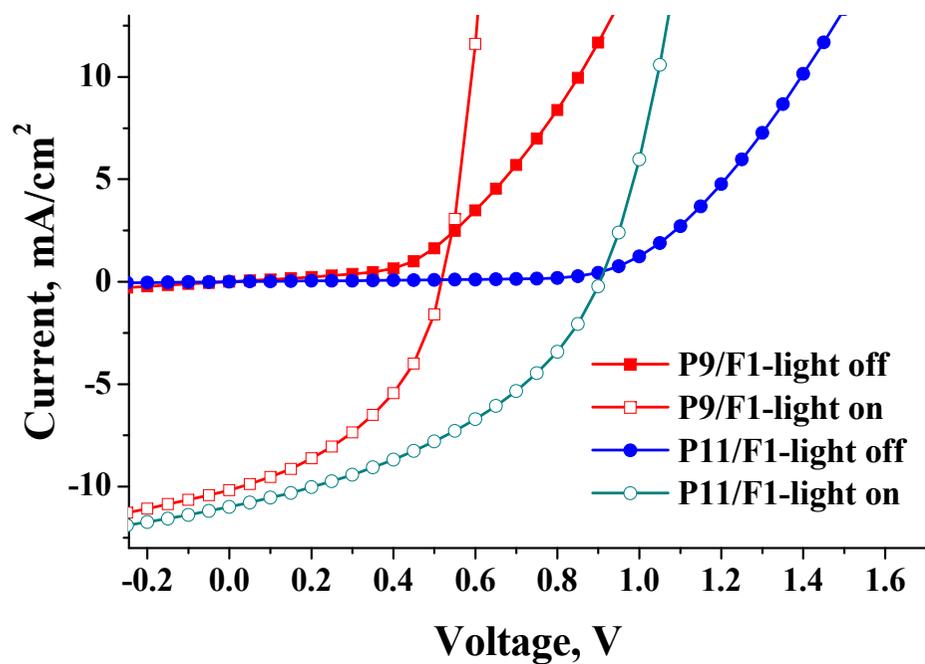
# I-V characteristics and IPCE spectra of low band gap copolymers



P9 (R = - Oct)



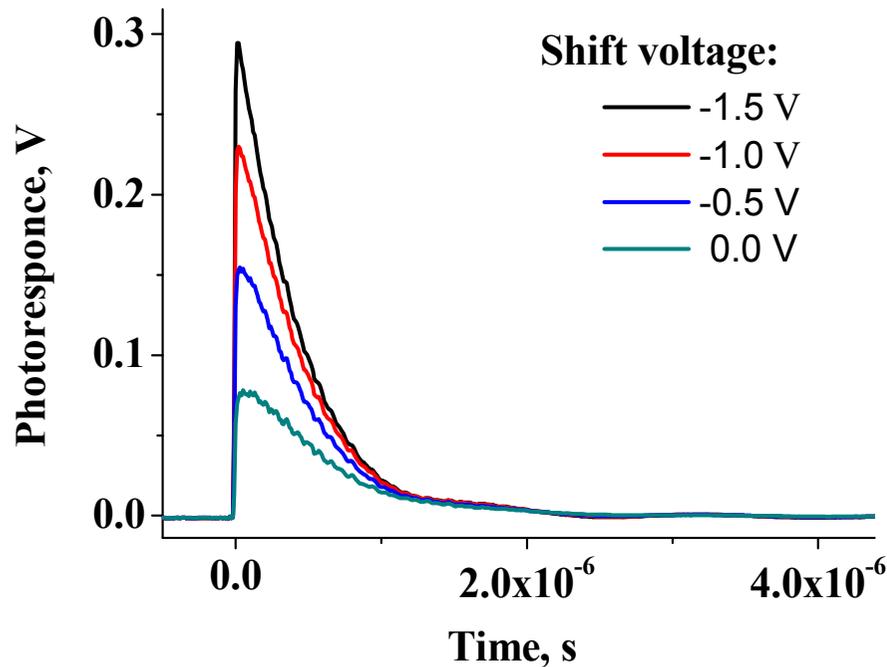
P11 (R = - Oct)



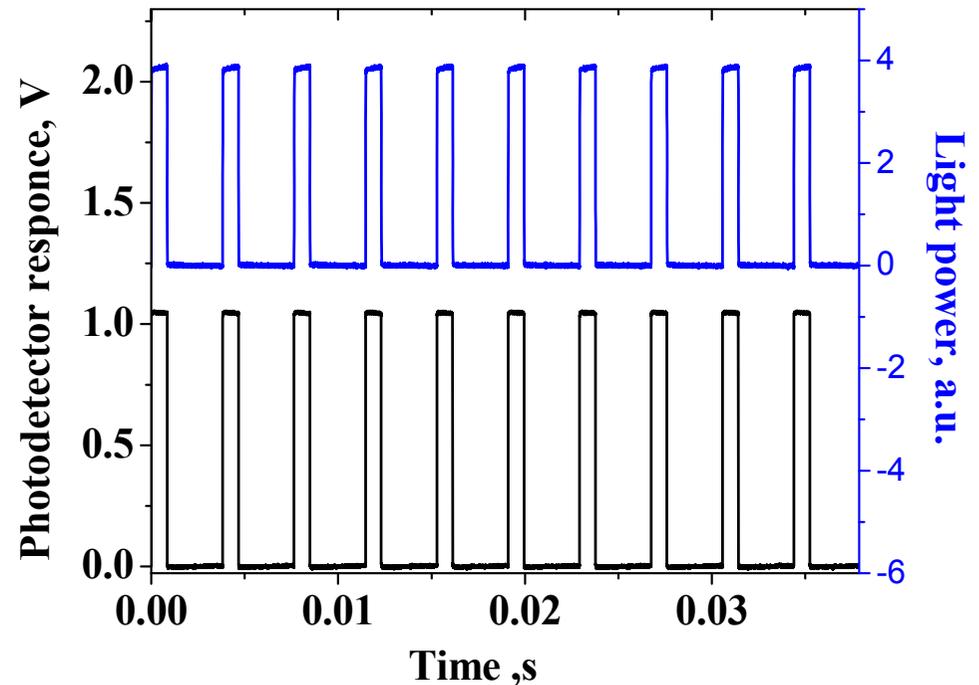
**P9:**  $I_{sc} = 10.23 \text{ mA/cm}^2$ ,  $V_{oc} = 0.5\text{V}$ ,  $FF = 41\%$ ,  $PCE = 2.1\%$

**P11:**  $I_{sc} = 10.50 \text{ mA/cm}^2$ ,  $V_{oc} = 0.9\text{V}$ ,  $FF = 42\%$ ,  $PCE = 4.0\%$

## Photodetectors based on P11/[60]PCBM blend



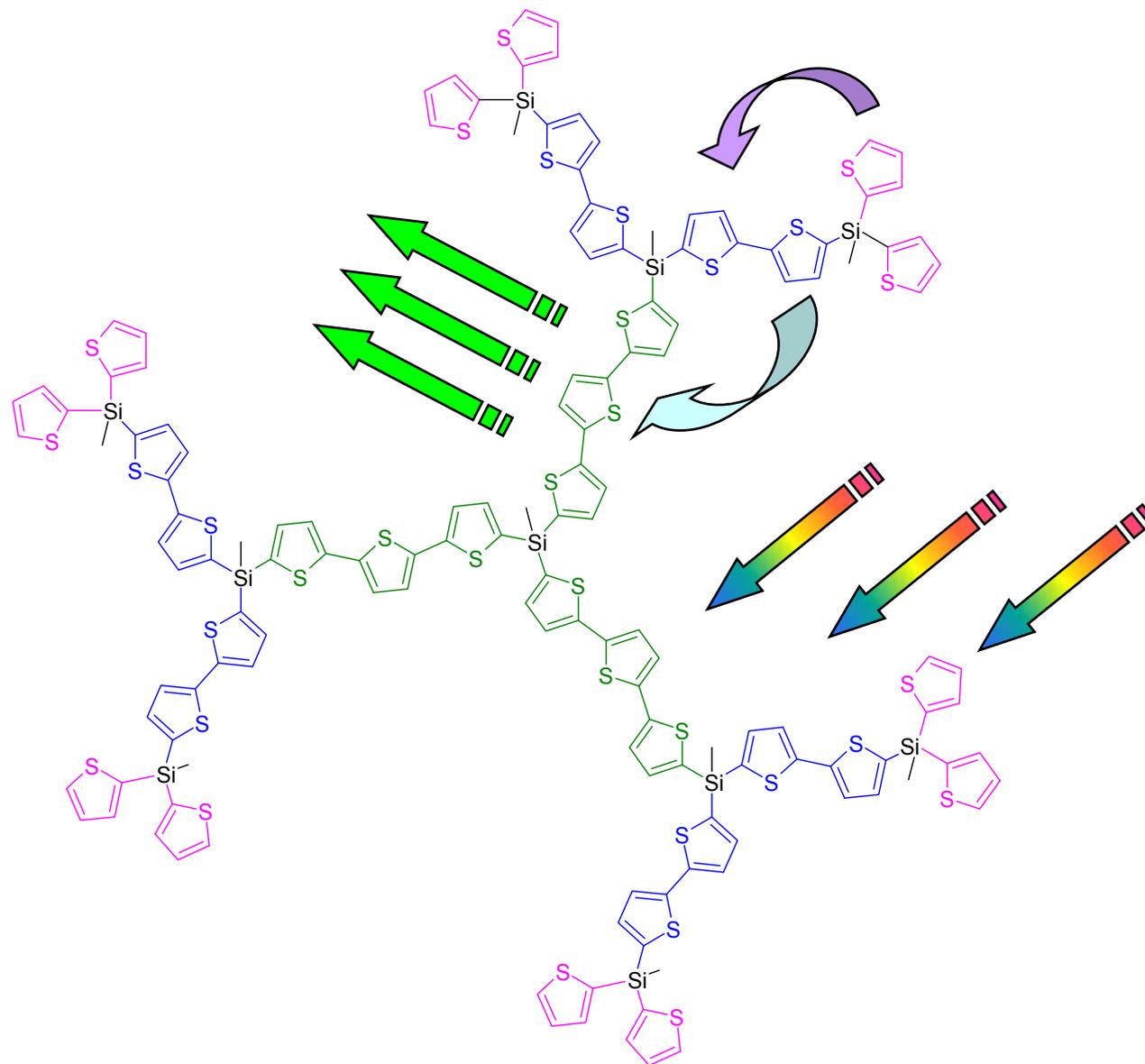
Transient response of the organic photodetector to a 10 ns light pulse from a nitrogen laser (337 nm) at different shift voltages. The active area was 0.5 cm<sup>2</sup> and a load resistance of 16 Ω.



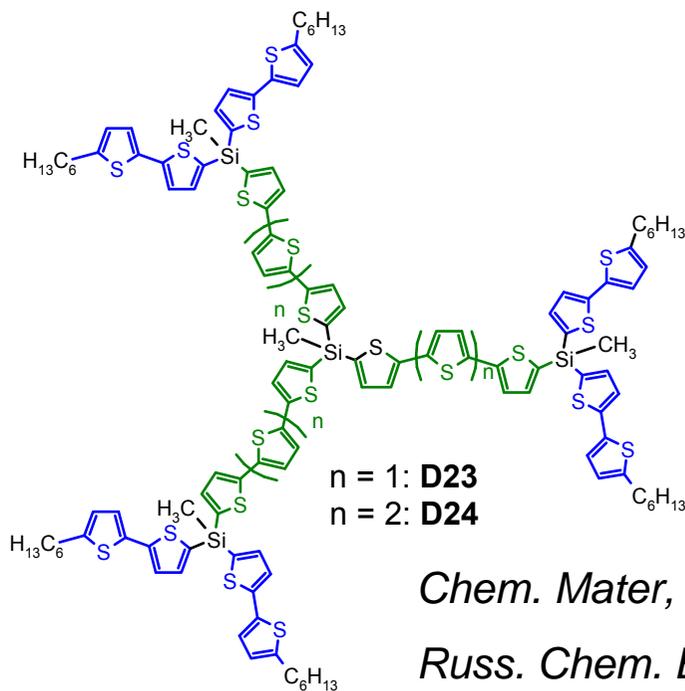
Detection of 1 ms light pulses of blue LED modulated at 250 Hz with the organic photodetector. Black line - photodetector response, blue line - light power.

**Response time ~30-40 ns, decay time ~1 μs.**

# Organosilicon nanostructures luminophores and “molecular antennae” effect

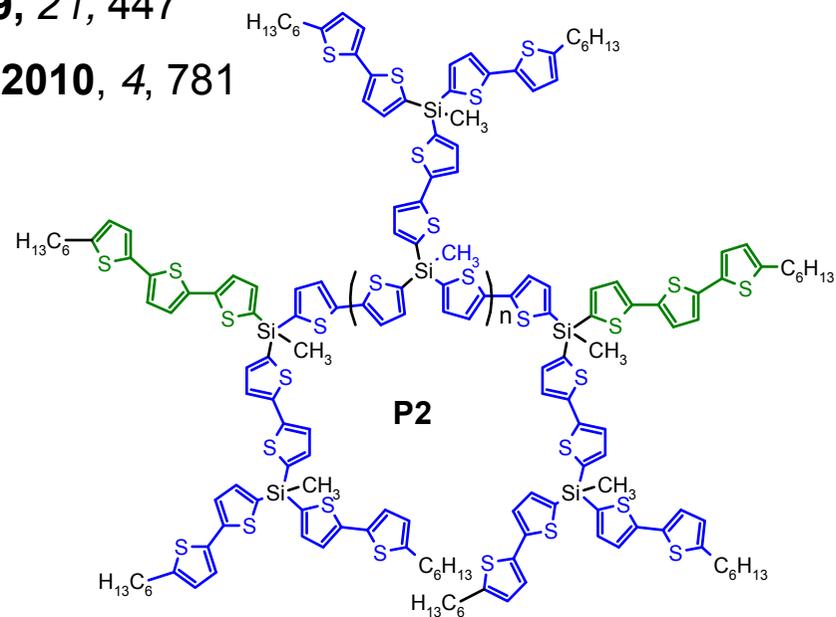
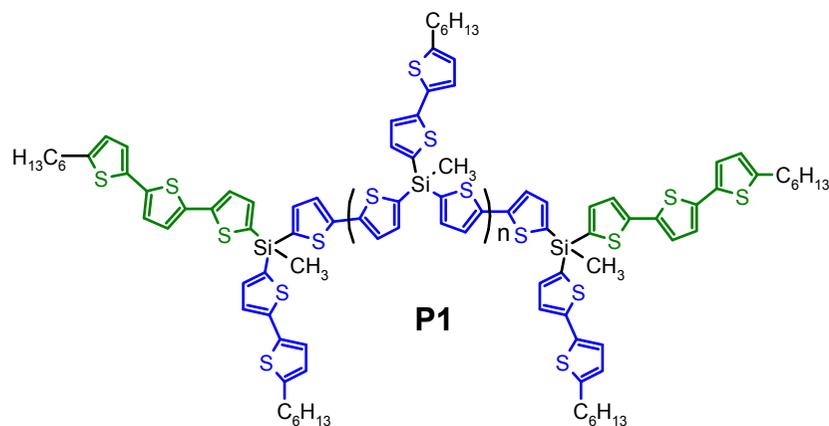
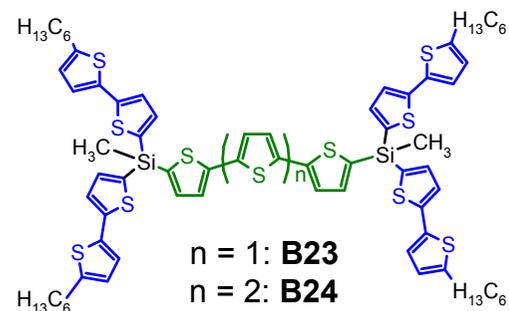


# The first organosilicon “molecular antennas”



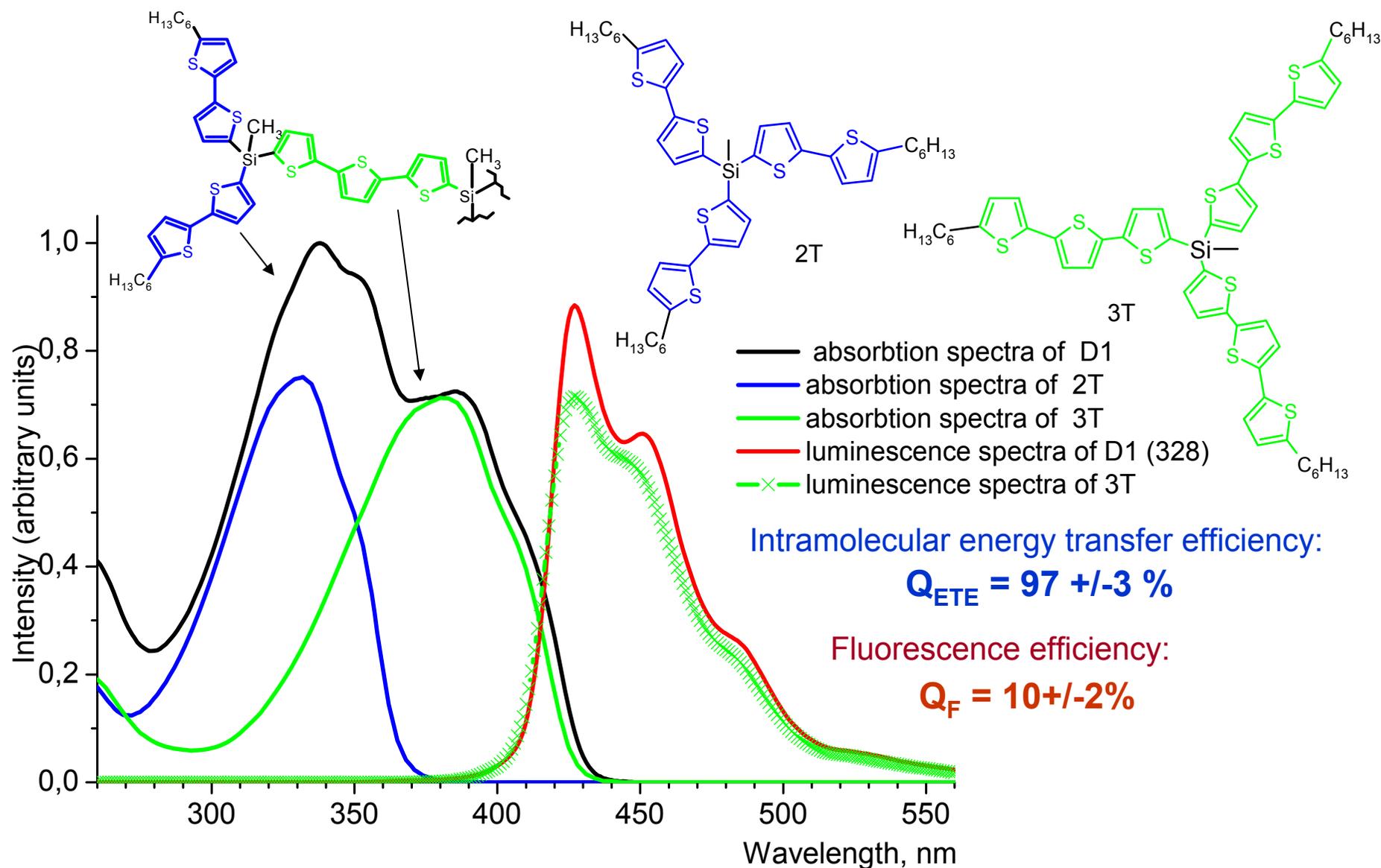
*Chem. Mater*, **2009**, *21*, 447

*Russ. Chem. Bull*, **2010**, *4*, 781



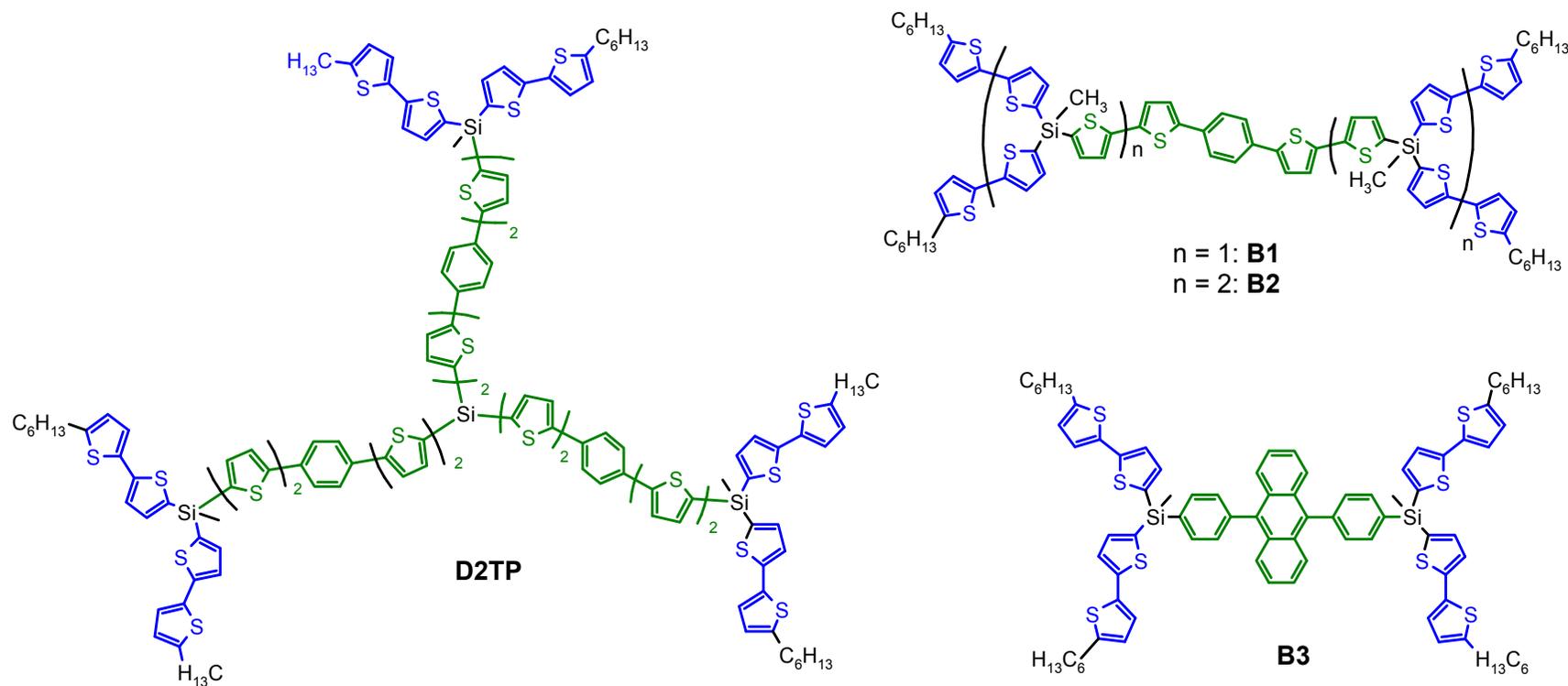
*Macromolecules* **2012**, *45*, 2014

# Absorption and luminescence spectra of dendrimer D23 and model stars



**Absorption spectra of dendrimer D23 consists of a absorption bands of its 2T and 3T components, but its luminescence spectra coincides with those of 3T fragments independently of excitation wavelength**

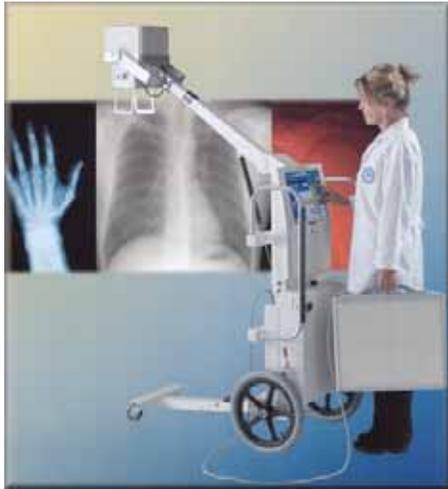
# Highly luminescent oligoarylsilane “molecular antennas”



*Mendeleev Commun.* **2011**, *21*, 89

Compound	$\lambda_{\text{abs}}$ , nm	$Q_{\text{F}}$ , %	$\lambda_{\text{lum}}$ nm	$Q_{\text{ETE}}$ , %
<b>D2TP</b>	336, 407	<b>46</b>	<b>456/487</b>	<b>88 +/- 3</b>
<b>B1</b>	336, 404	<b>55</b>	<b>456/487/521</b>	<b>99 +/- 1</b>
<b>B2</b>	337, 404	<b>55</b>	<b>456/486/522</b>	<b>90 +/- 10</b>
<b>B3</b>	331, 375, 396	<b>80</b>	<b>418</b>	<b>82 +/- 10</b>

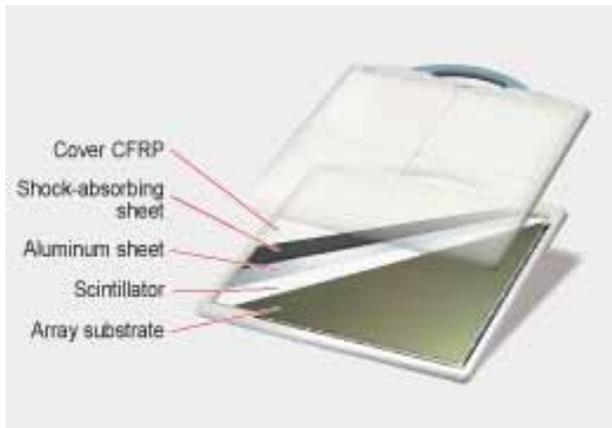
# Plastic scintillators and their applications



In medicine



Radiation control on nuclear power stations



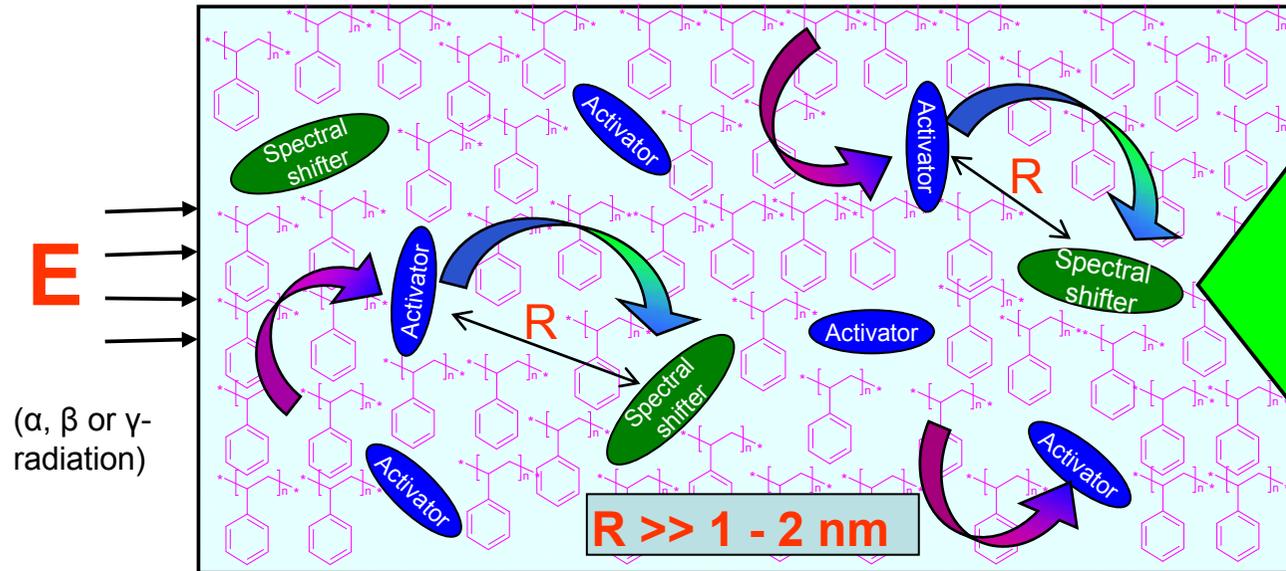
X-ray tomography



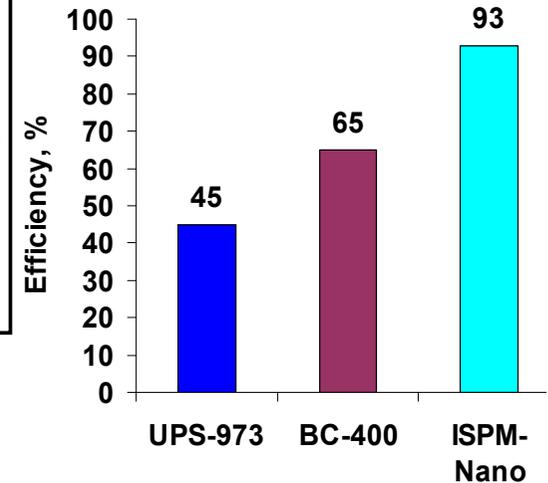
Radiation control at the borders

# Application in organic photonics: plastic scintillators

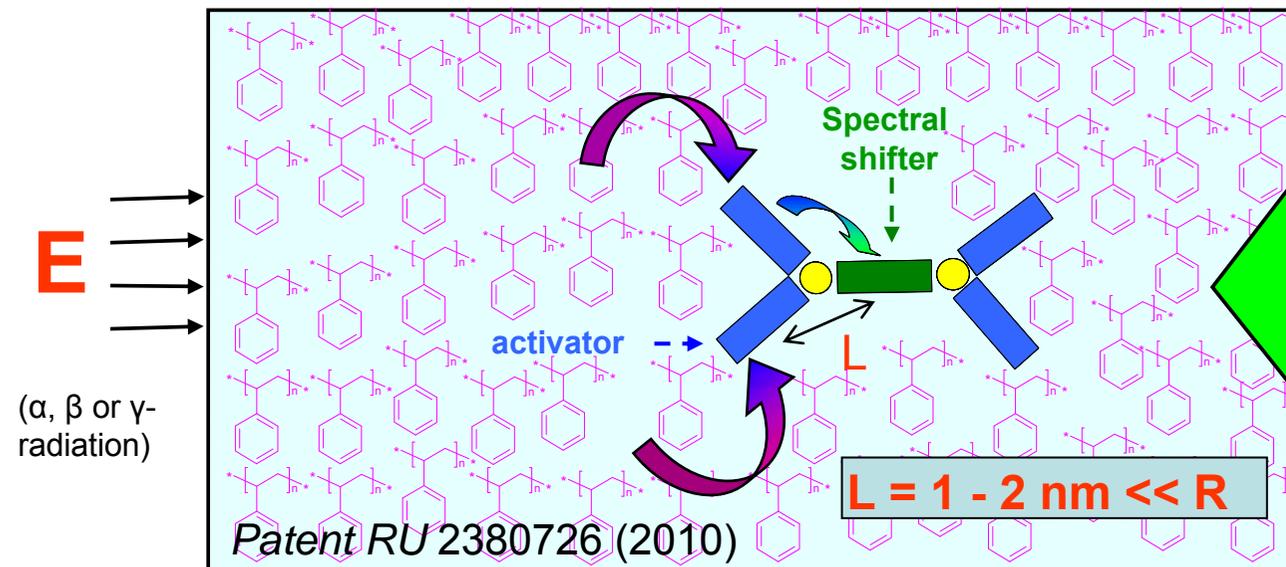
## Classical polymeric scintillator



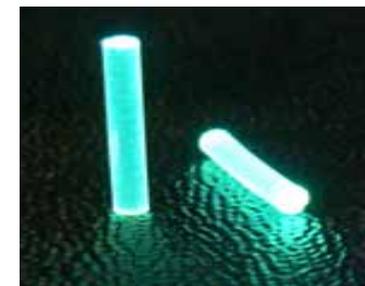
Efficiency relative to anthracene crystal



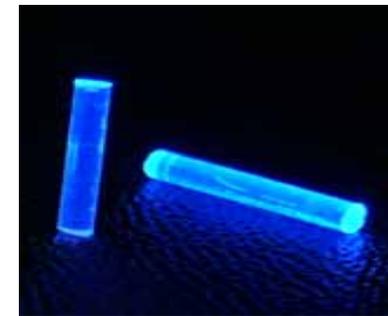
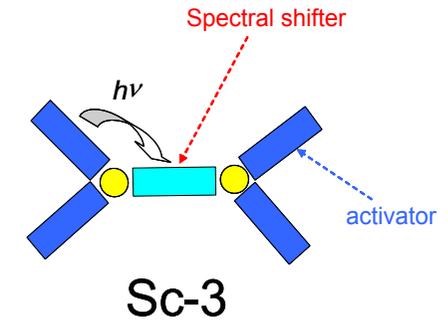
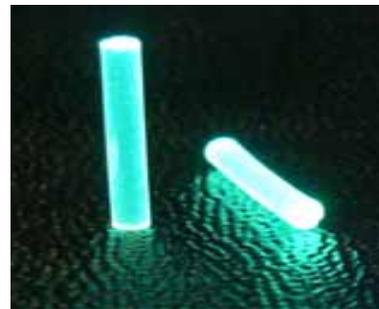
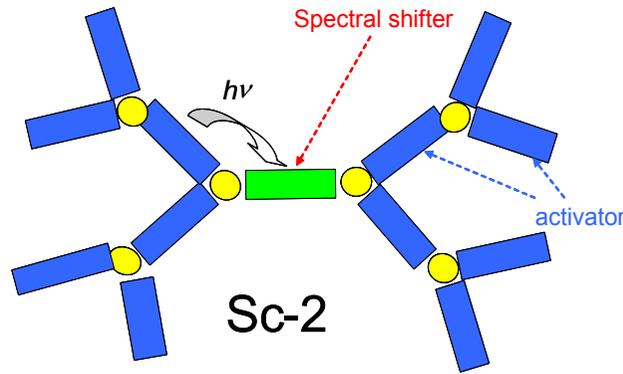
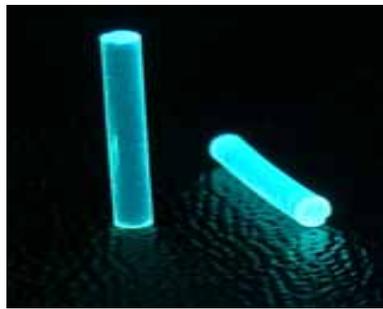
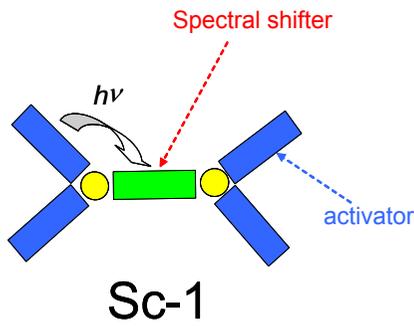
## New scintillator with nanostructured luminophores



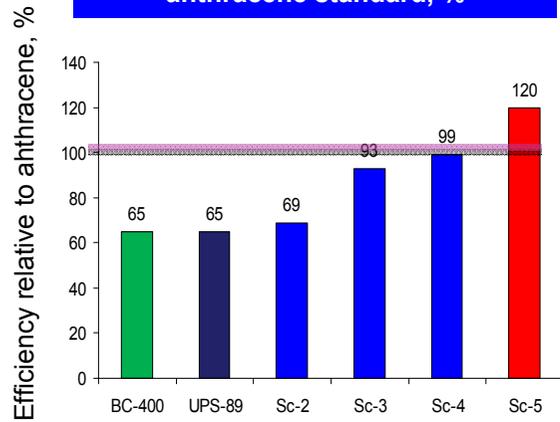
Nanoscintillator under UV irradiation



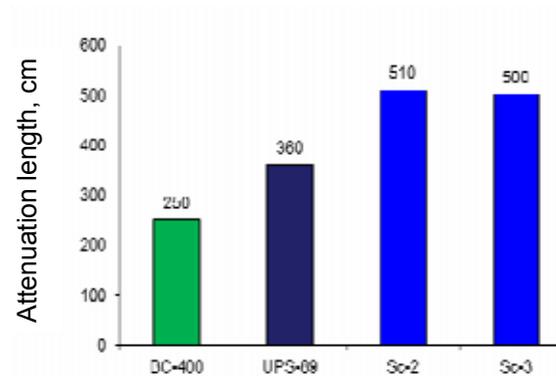
# Polystyrene nanoscintillators



Scintillation efficiency relative to anthracene standard, %



Attenuation length on the emission wavelength, cm

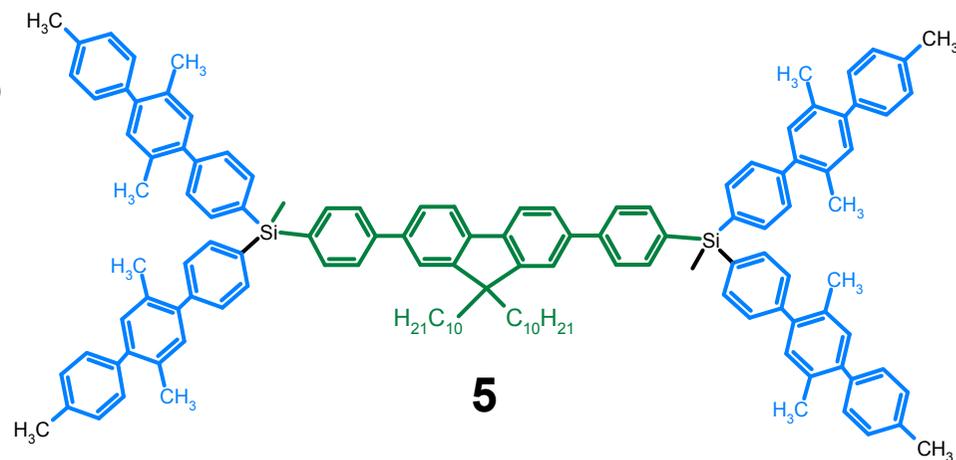
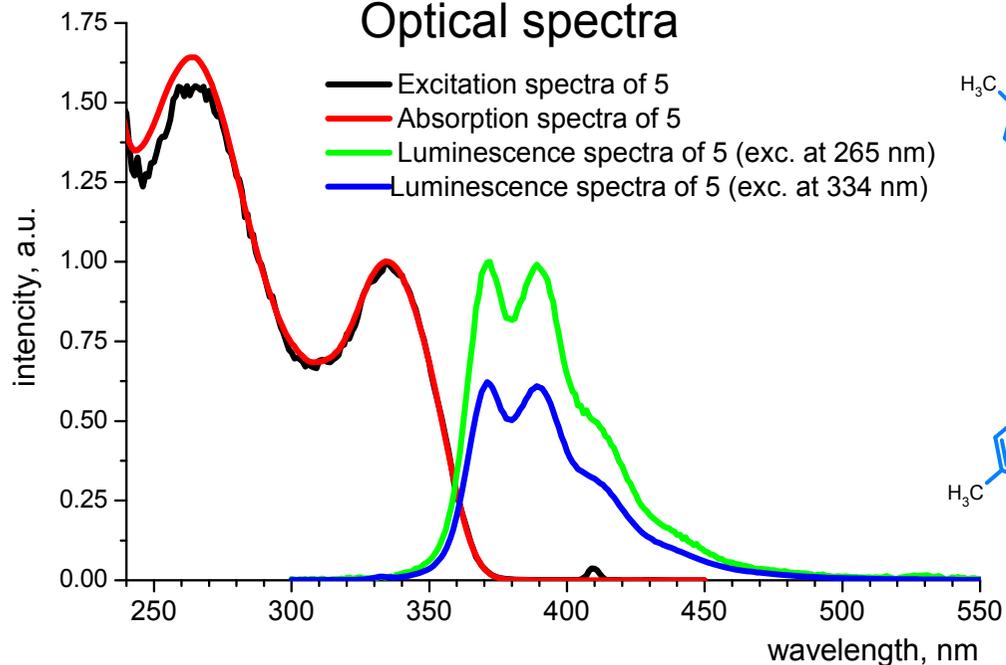


BC-400 – scintillator “Bicron”  
UPS-973- scintillator “Amcrys-H”

Plastic scintillators with the efficiency exceeding those of anthracene crystals!

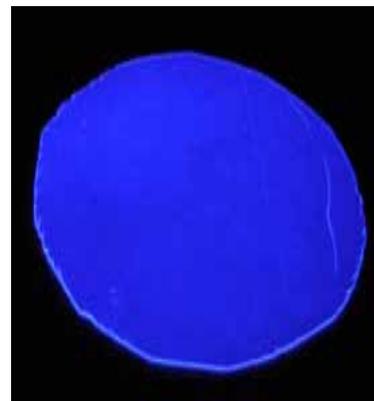
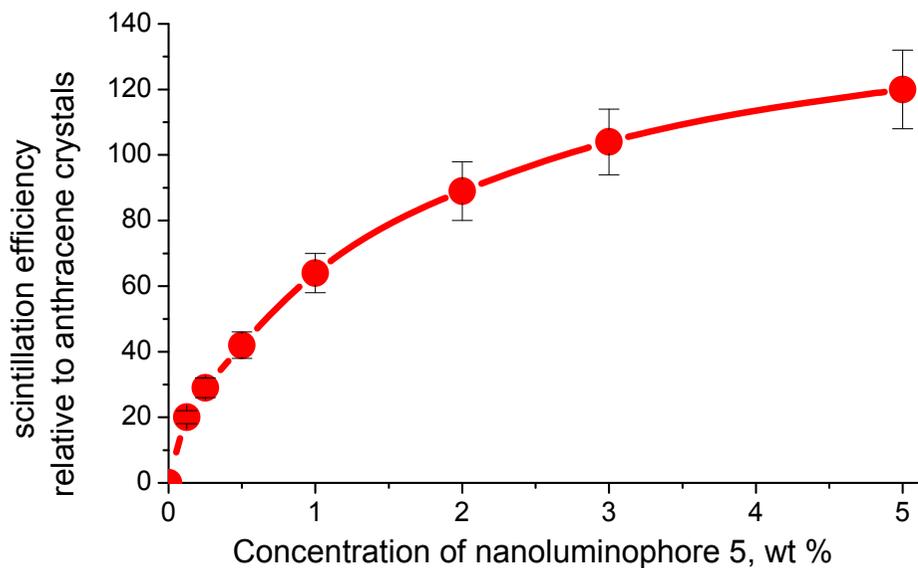
# Polystyrene nanoscintillators

## Optical spectra

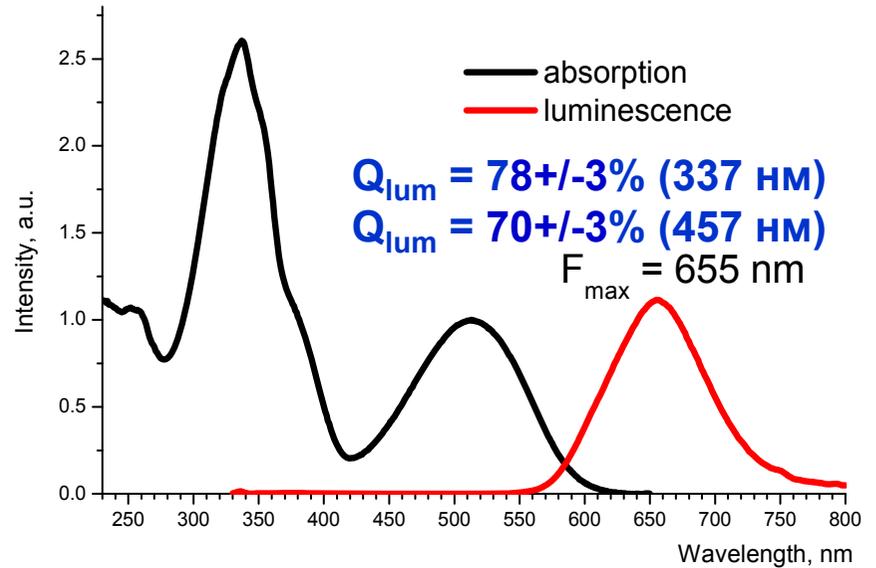
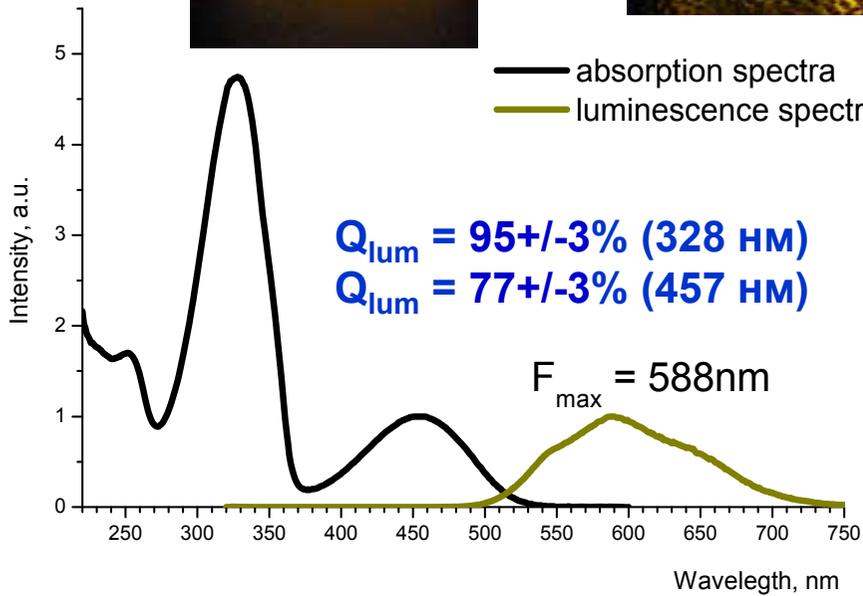
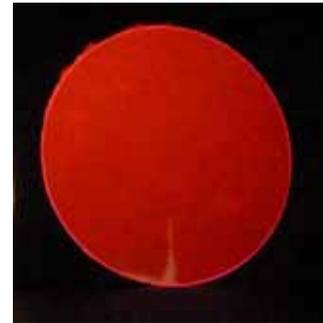
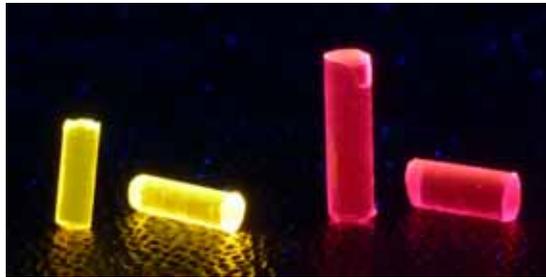
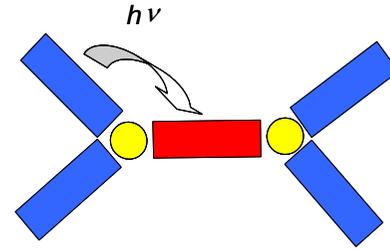
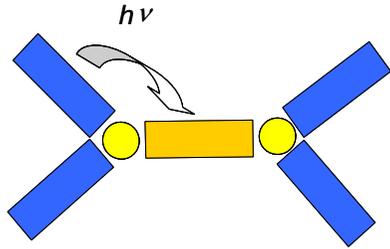


$$Q_{lum} = 85 \pm 5\%$$

$$E_{transfer} = 98 \pm 2\%$$

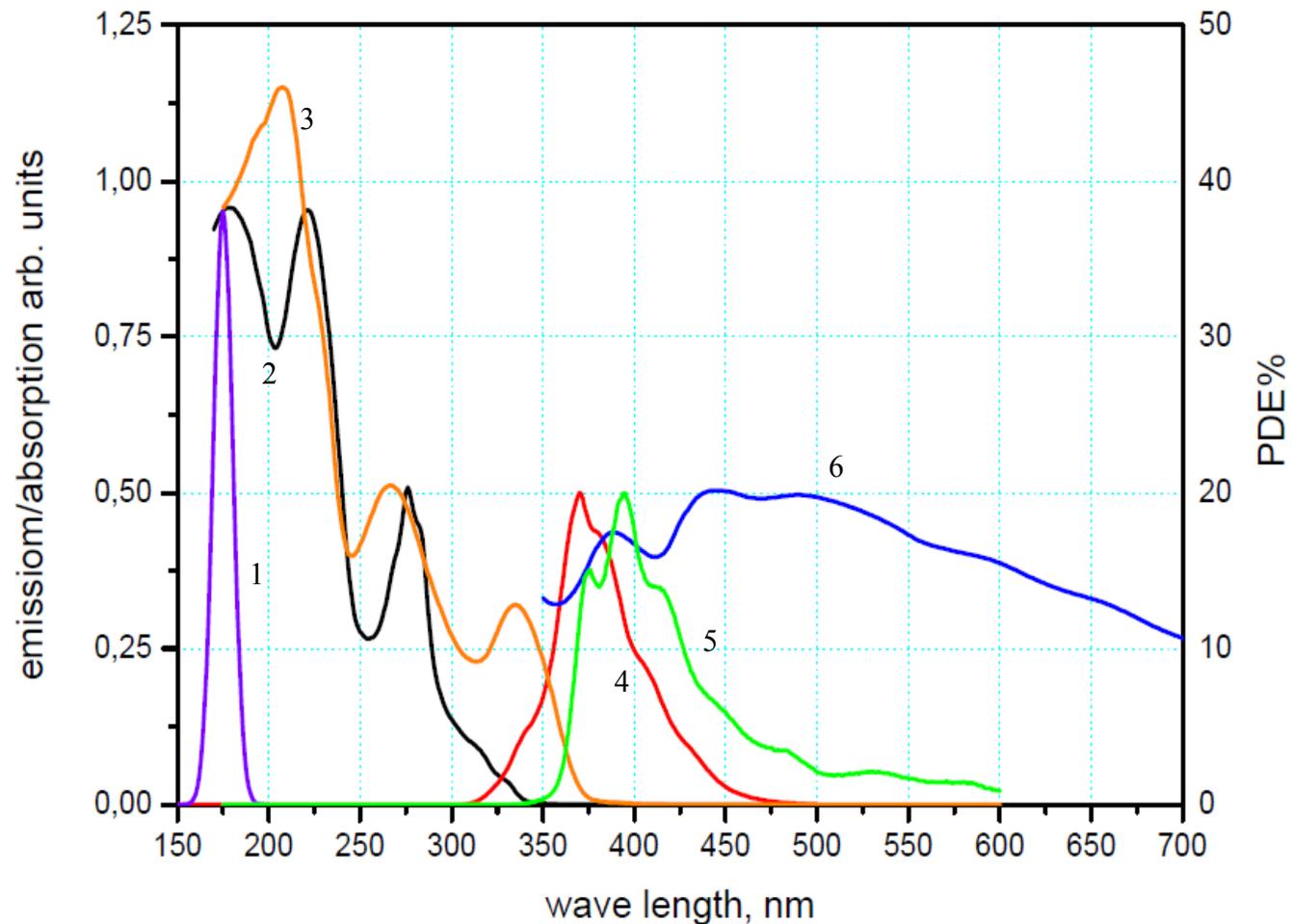


# Novel organosilicon wavelength shifters



Efficient yellow and red wavelength shifters have been created

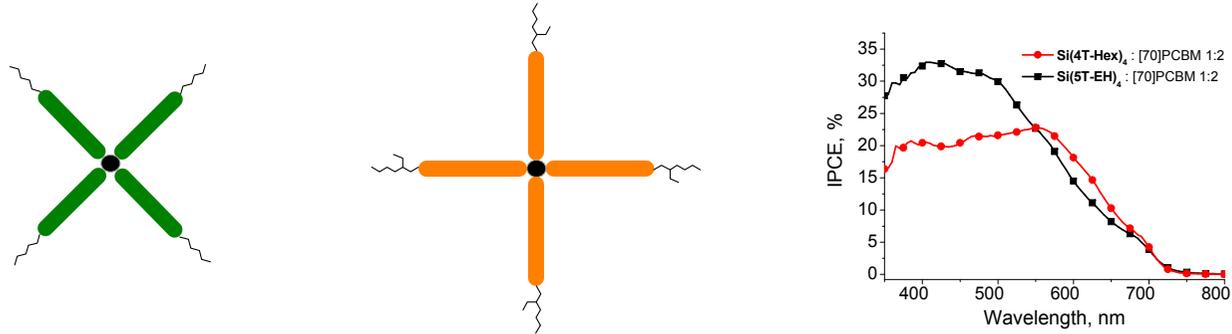
## VUV Wavelength sifters for noble gas detectors



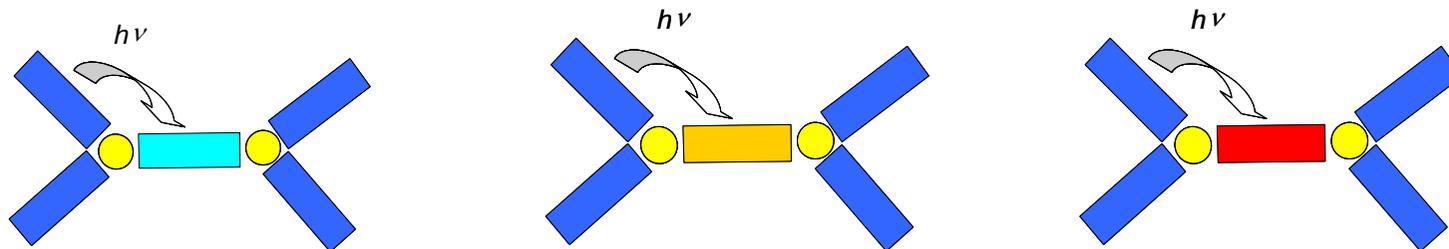
**Fig 1.** Emission spectrum of LXe (1), absorption spectrum of p-terphenyl (2), absorption spectrum of new WLS (3), emission spectrum of p-terphenyl (4), emission spectrum of new WLS (5), photon detection efficiency (PDE) of the CPTA “blue-sensitive” photodiode (6), right axis.

# Conclusions

- Soluble oligothiophenesilane multipods are promising materials for organic BHJ solar cells and photodetectors with the response time of 20 - 30 ns .



- Silicon atoms brake the conjugation between the adjacent luminophores that allows creation of organosilicon nanostructured luminophores, which can be used in highly efficient and fast plastic scintillators and wavelength shifters.



- Light output of the “plastic nanoscintillators” can exceed those of the standard BC408 more than 1,6 times and even exceed the efficiency of anthracene crystals.

## Acknowledgements

### **ISPM RAS (Russia)**

Y.N. Luponosov  
E.A. Kleymyuk  
E.A. Myshkovskaya  
M.S. Polinskaya  
Prof. A.M. Muzafarov

### **IPCP RAS (Russia)**

**P.A. Troshin**  
E.A. Khakina  
D.A. Susarova  
Prof. V.F. Razumov

### **INEOS RAS (Russia)**

M.I. Buzin  
A.P. Pleshkova  
S.N. Peregudova

### **INEP CP RAS (Russia)**

Y.L. Moskvina  
S.D. Babenko

### **ITEP (Russia)**

**D.Y. Akimov**  
A.V. Akindinov  
I.S. Alexandrov  
A.A. Burenkov  
M.V. Danilov  
A.G. Kovalenko  
V.N. Stekhanov

### **H.C. Starck Clevios GmbH** (Germany)

Dr. Stephan Kirchmeyer  
Dr. Timo Meyer-Friedrichsen  
Dr. Andreas Elschner

\$\$\$ Russian Foundation for Basic Research, Presidium of Russian Academy of Sciences, Russian Ministry for Science and Education, H.C. Starck GmbH

# Thank you for your attention!